

A New View of the SIT

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International Workshop

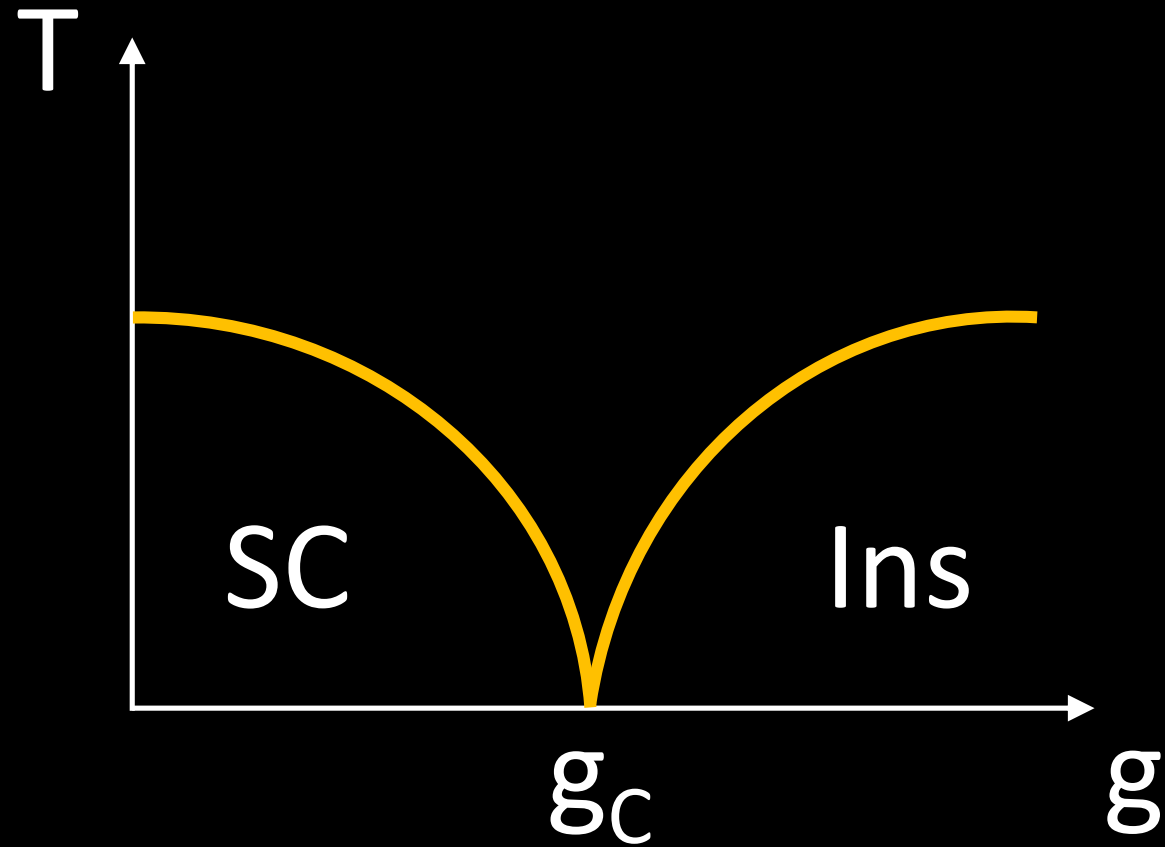
“Strongly disordered and inhomogeneous superconductivity”

Grenoble (France), 21-22 November 2016

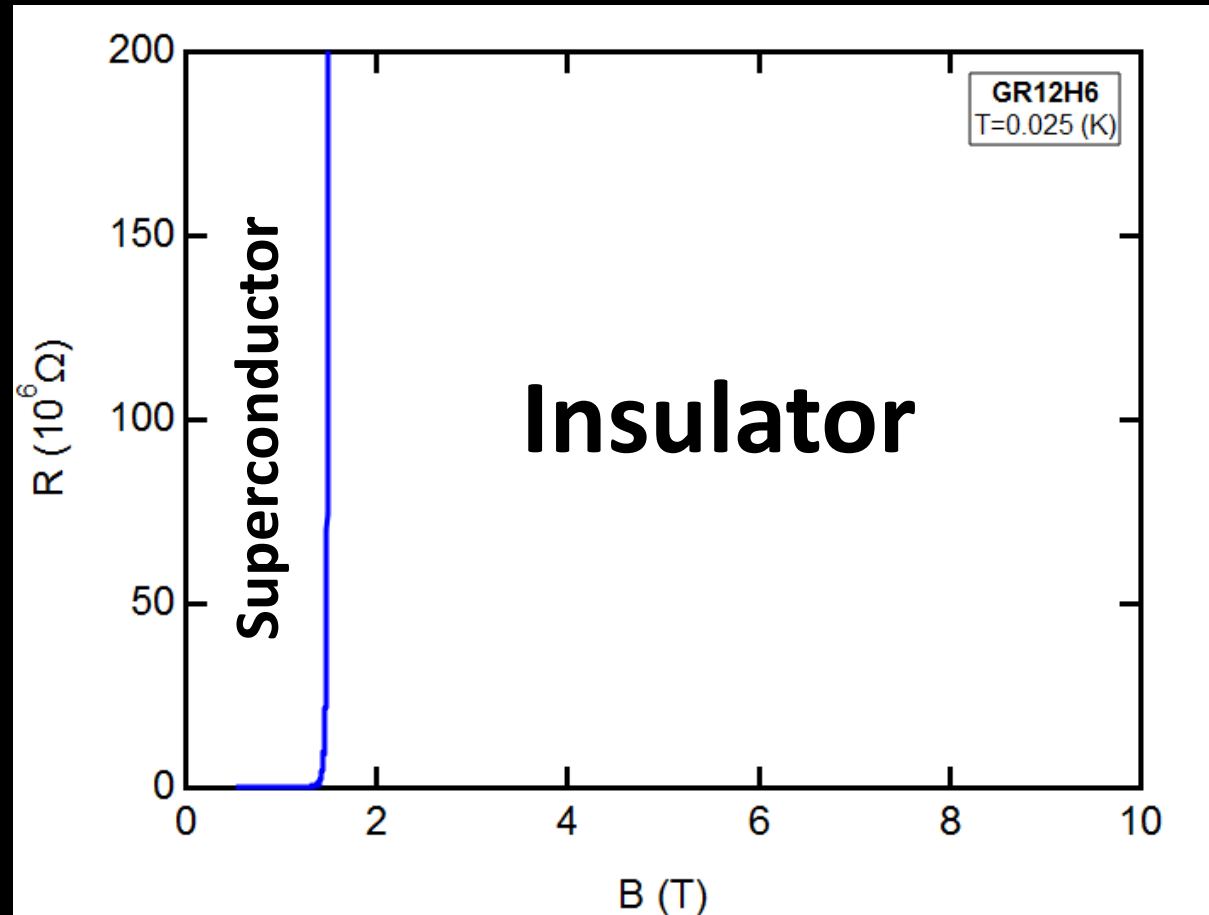


Superconductor-Insulator Transition (SIT)

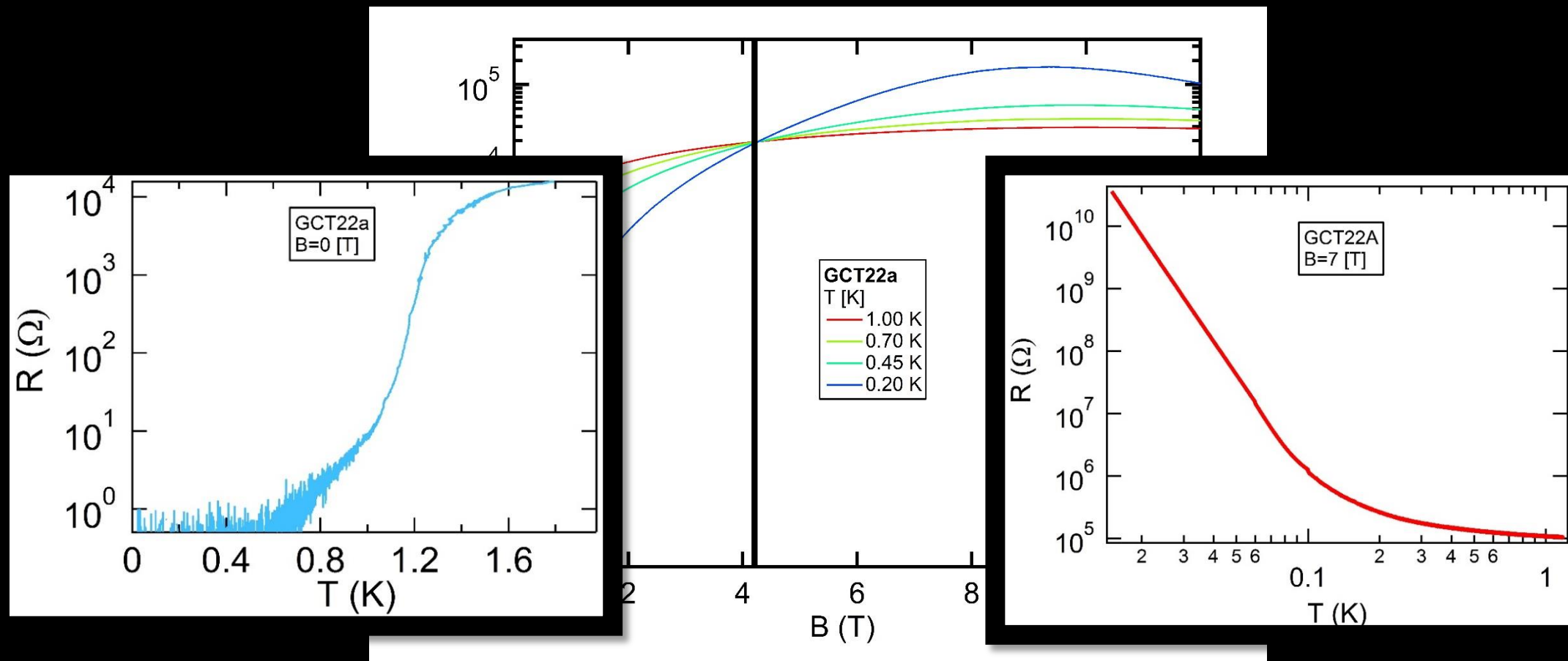
Quantum Phase Transition



Quite Sharp.



B Driven SIT in a:InO

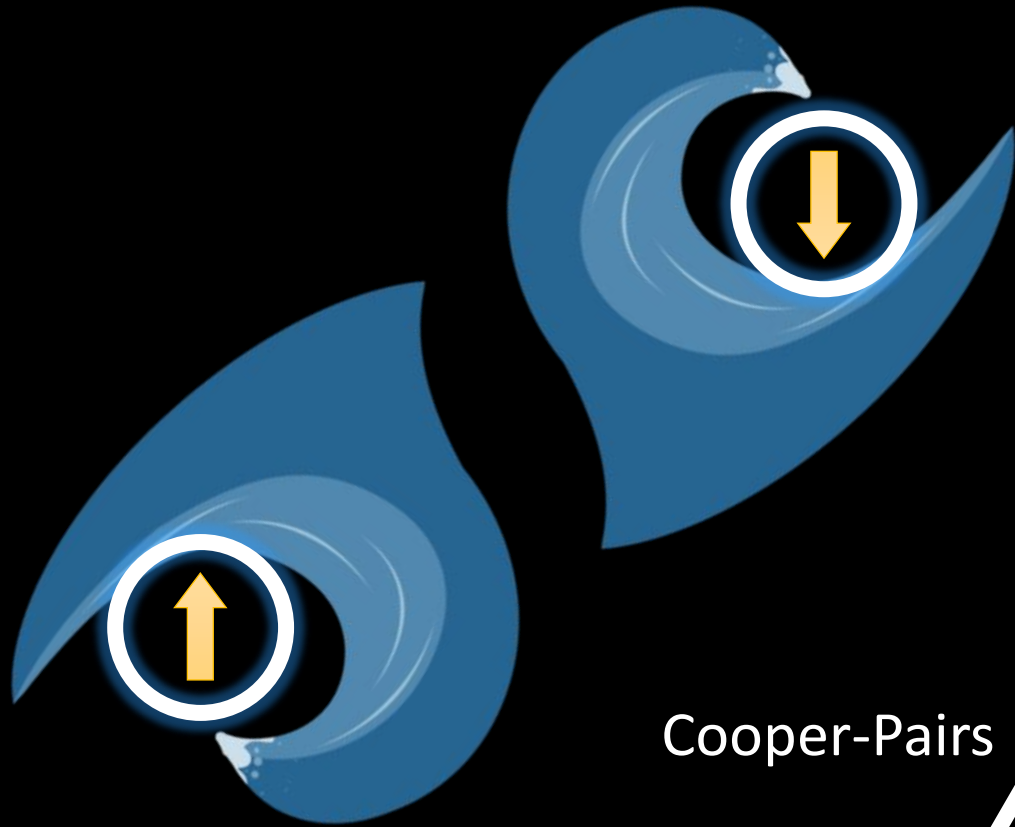


Cooper-Pair Insulator

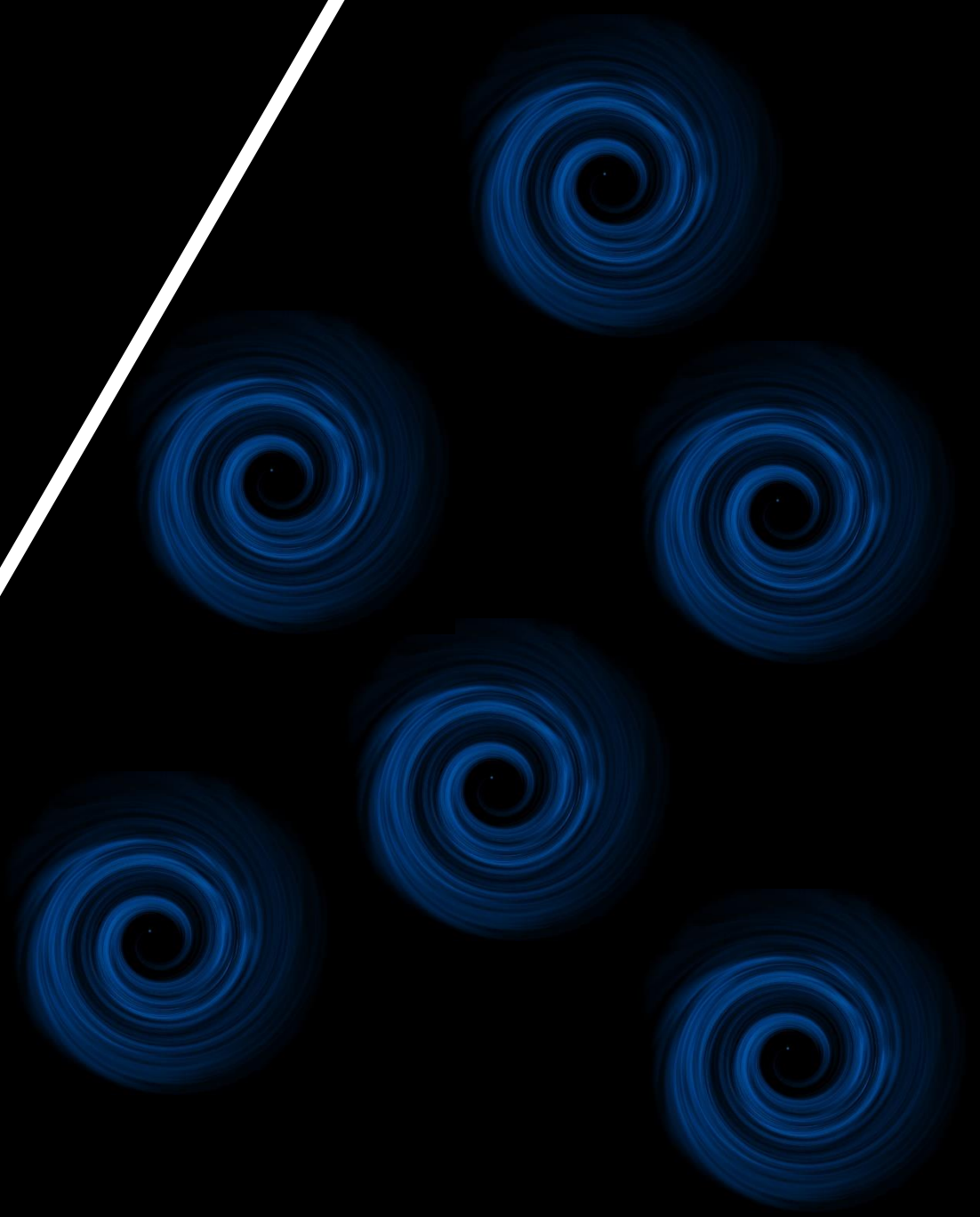
CPI – Supporting Theoretical Arguments

- M. P. A. Fisher, Phys. Rev. Lett. 65, 923 (1990)
- V. M. Galitski et al, Phys. Rev. Lett. 95, 077002 (2005)
- Dubi, Meir and Avishai, NATURE | Vol 449 | (2007)
- M. V. Feigel'man et al, Phys. Rev. Lett. 98, 027001 (2007)
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- D. Meidan and Y. Oreg, Phys. Rev. B 79, 214515 (2009)
- Müller and Shklovskii, Phys. Rev. B 79, 134504 (2009)
- Pokrovsky, Falco and Nattermann, Phys. Rev. Lett. 105, 267001 (2010)
- K. Bouadim, Y.L. Loh, M. Randeria, and N. Trivedi, Nature Physics 7, 889 (2011)
- Lages and Shepelyansky, Eur. Phys. J. B81, 2, (2011)
- S. Syzranov et al., Phys. Rev. Lett. 108, 256601 (2012)
- Burmistrov et al, PRB (2015)
- ...

Duality



Cooper-Pairs



Vortices

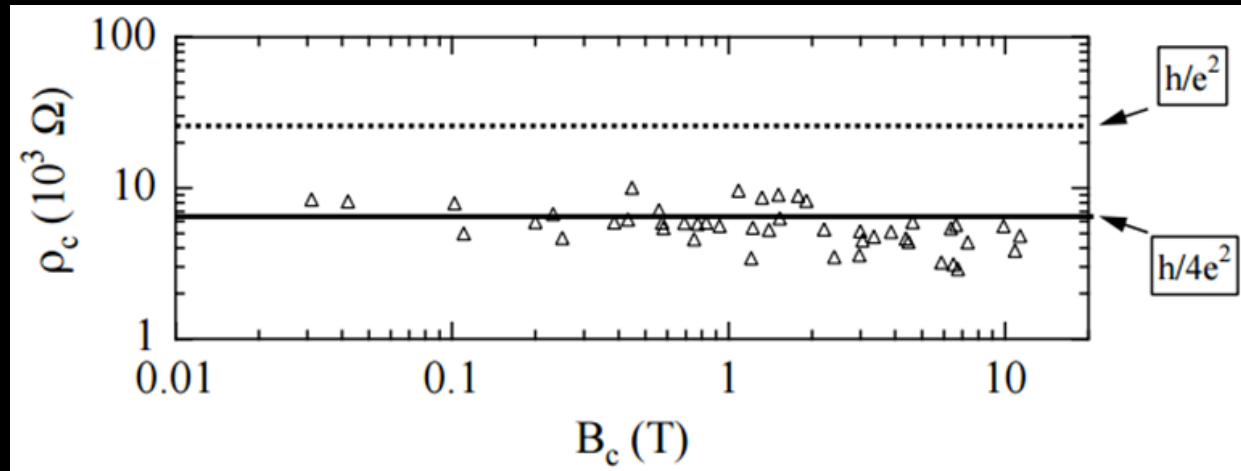
M. P. A. Fisher, Quantum phase transitions in disordered two-dimensional superconductors, Phys. Rev. Lett. 65, 923 (1990)

In JJA: Fazio, R. & Schön, G. Charge and vortex dynamics in arrays of tunnel junctions. Phys. Rev. B 43, 5307–5320 (1991).

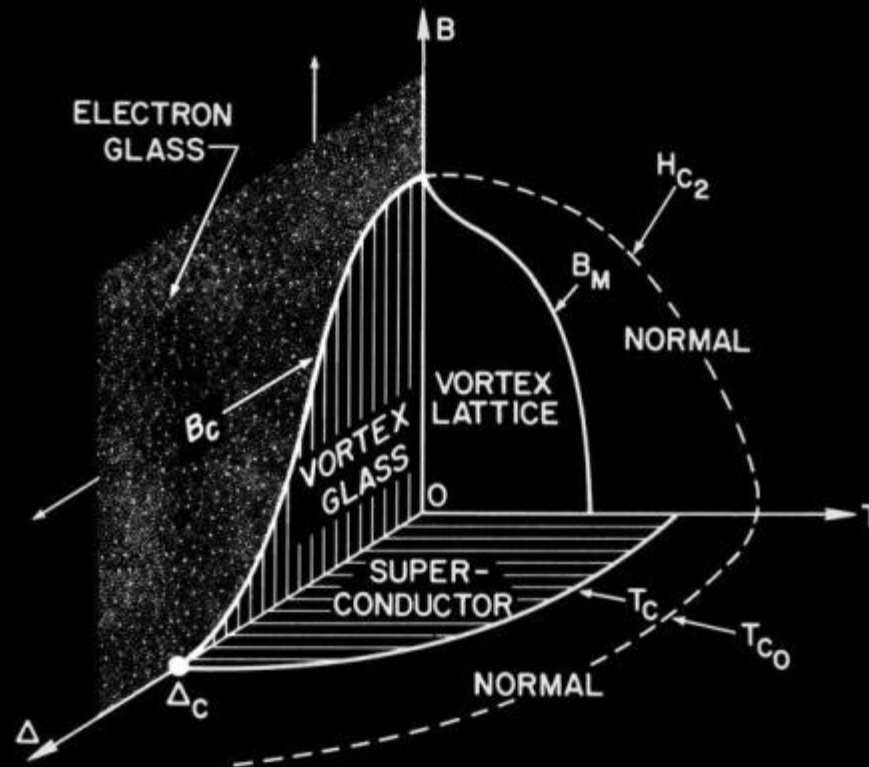
Vortex–Charge Duality-Symmetry

$$I \leftrightarrow V$$

$$\sigma = I/V \leftrightarrow \rho = V/I$$



Phase Diagram

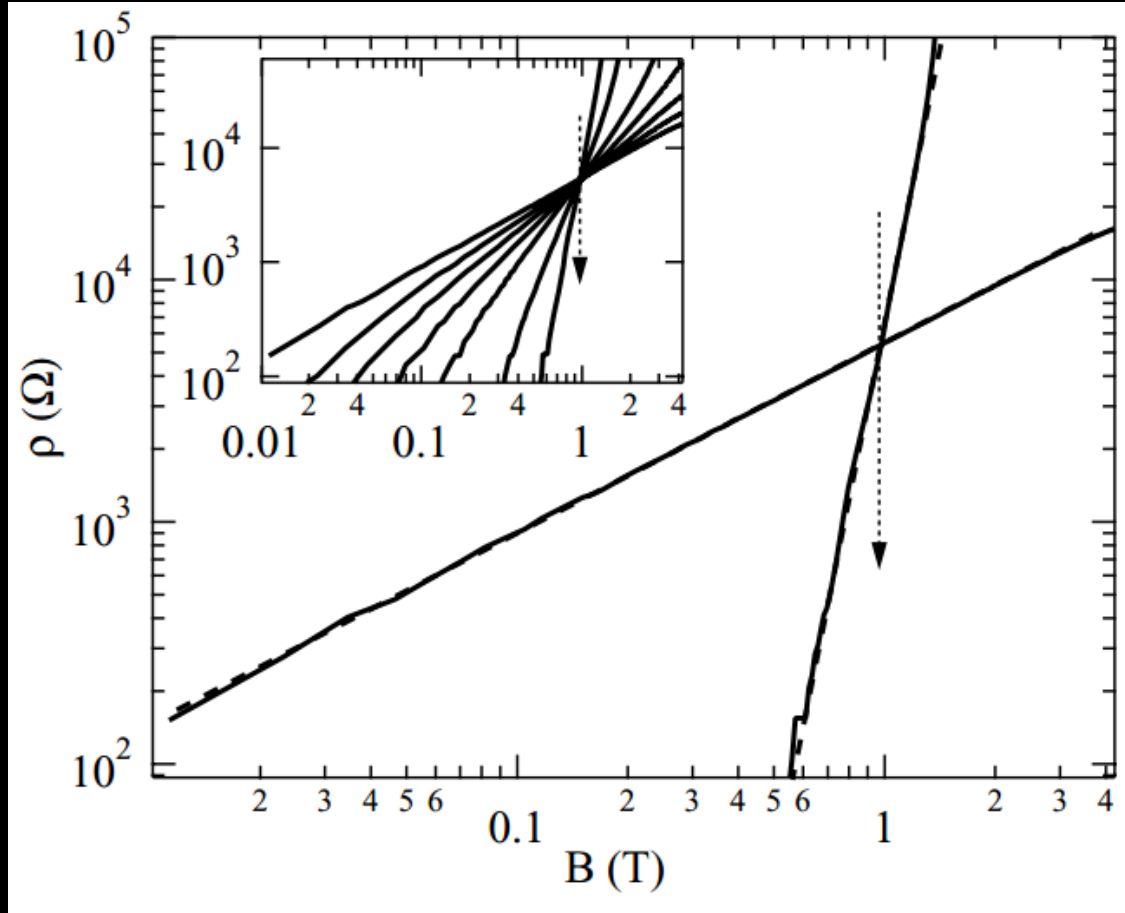


$T \neq 0 \rightarrow$ activation (pinning) energy

$$U = \frac{1}{2} T_c \log \frac{B_c}{B}$$

Expected power law resistivity

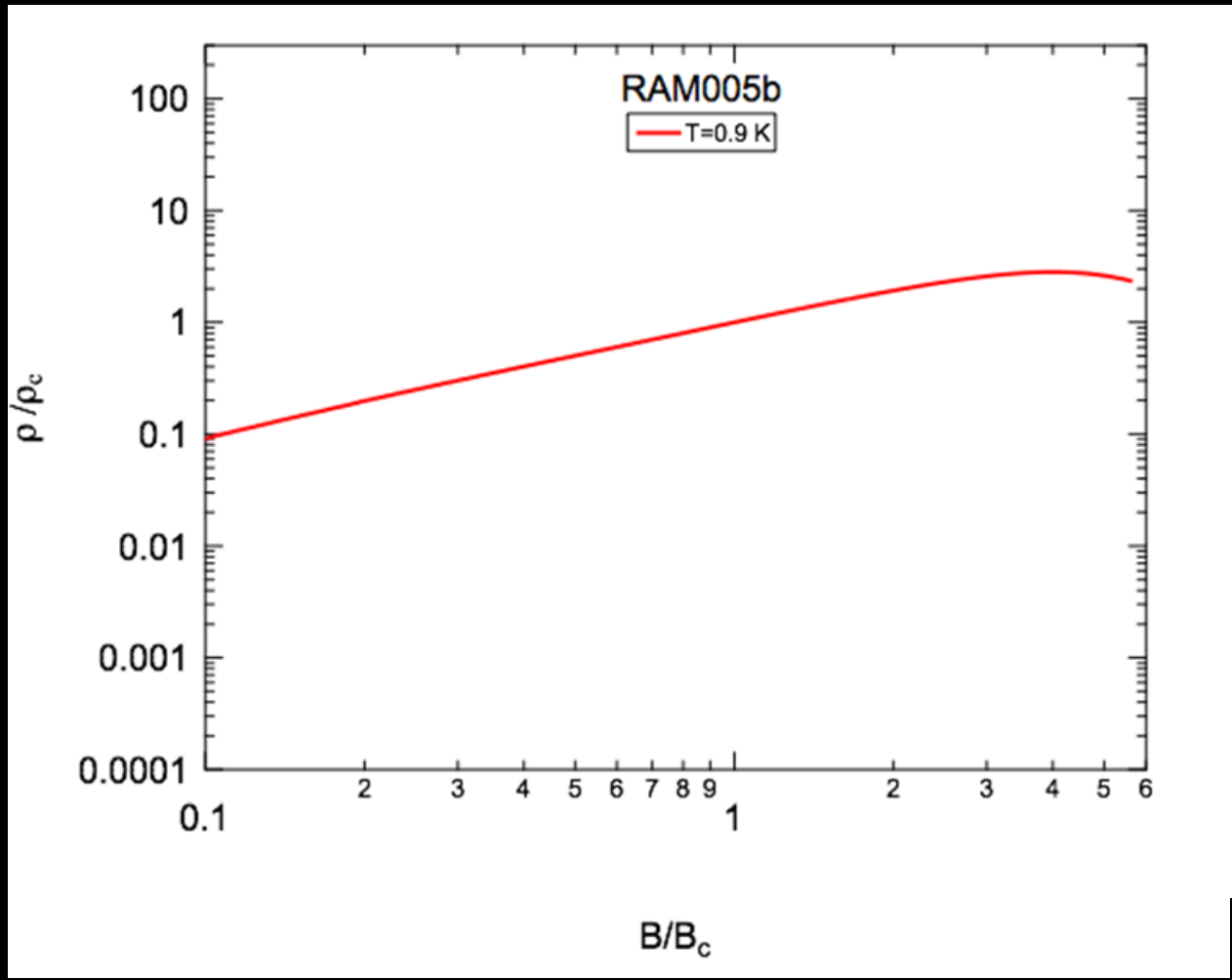
Measured Power law resistivity across SIT

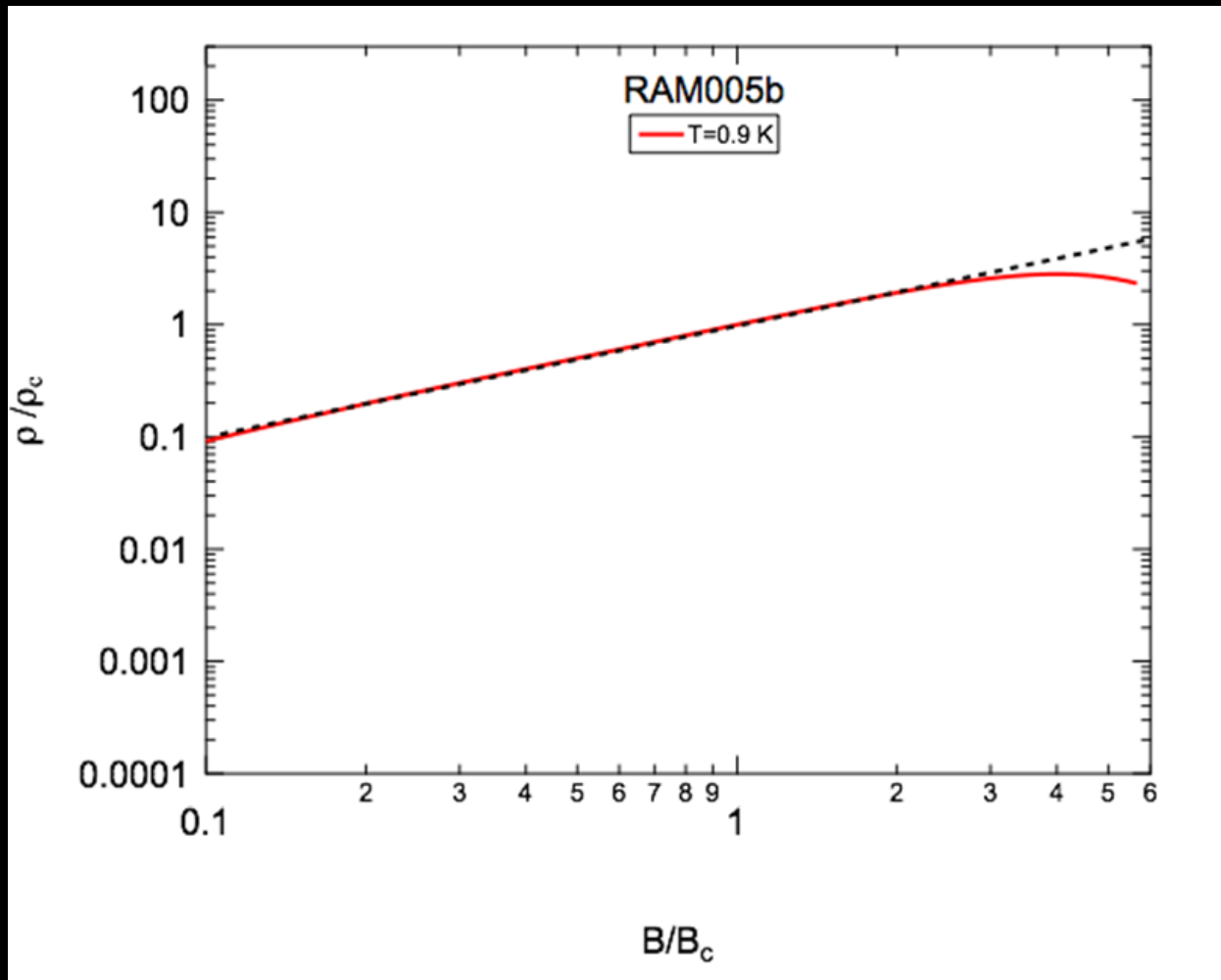


$$\rho(B, T) = \rho_C \left(\frac{B}{B_C} \right)^{T_0/2T}$$

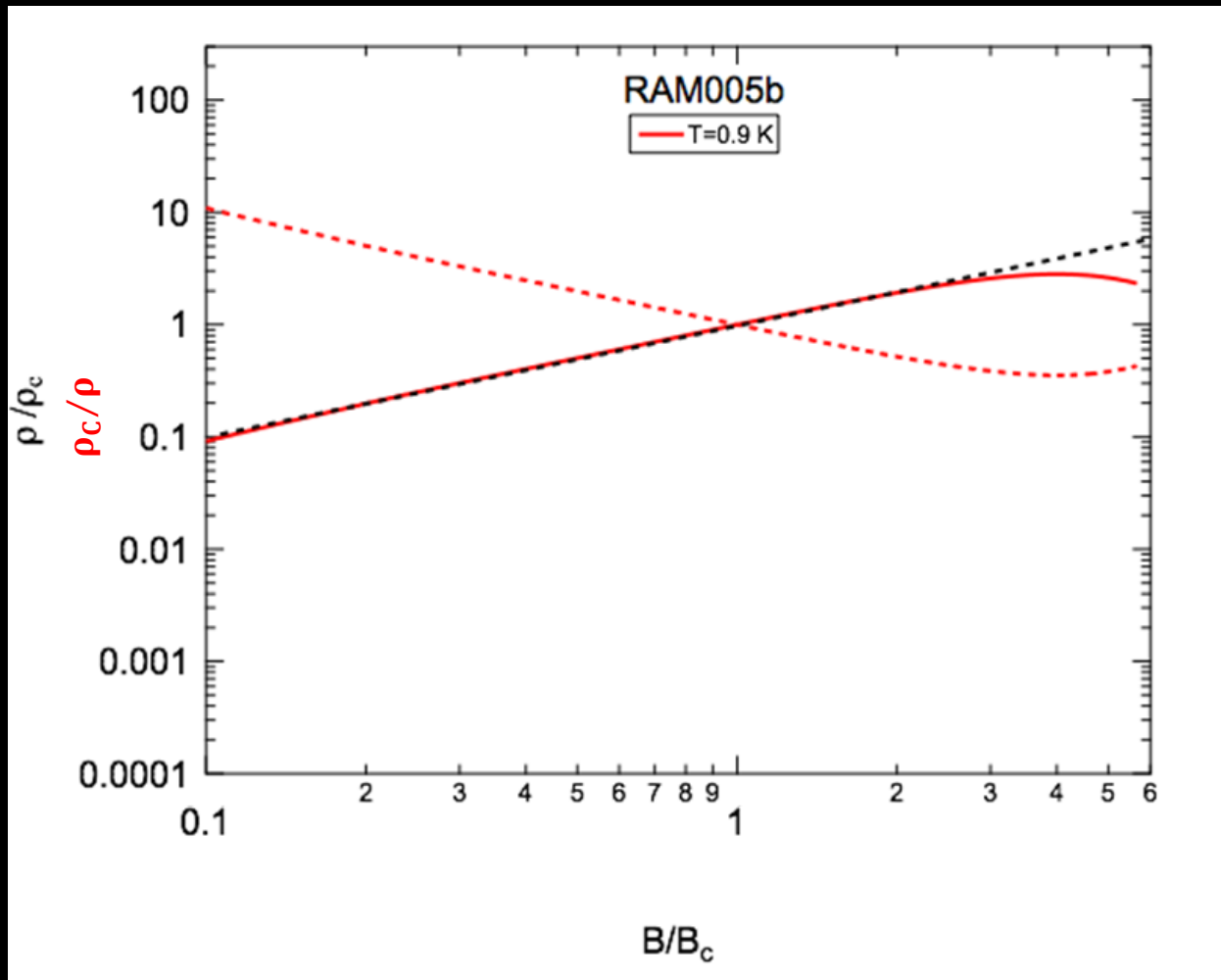
Duality Symmetry

$$\rho \leftrightarrow \sigma$$

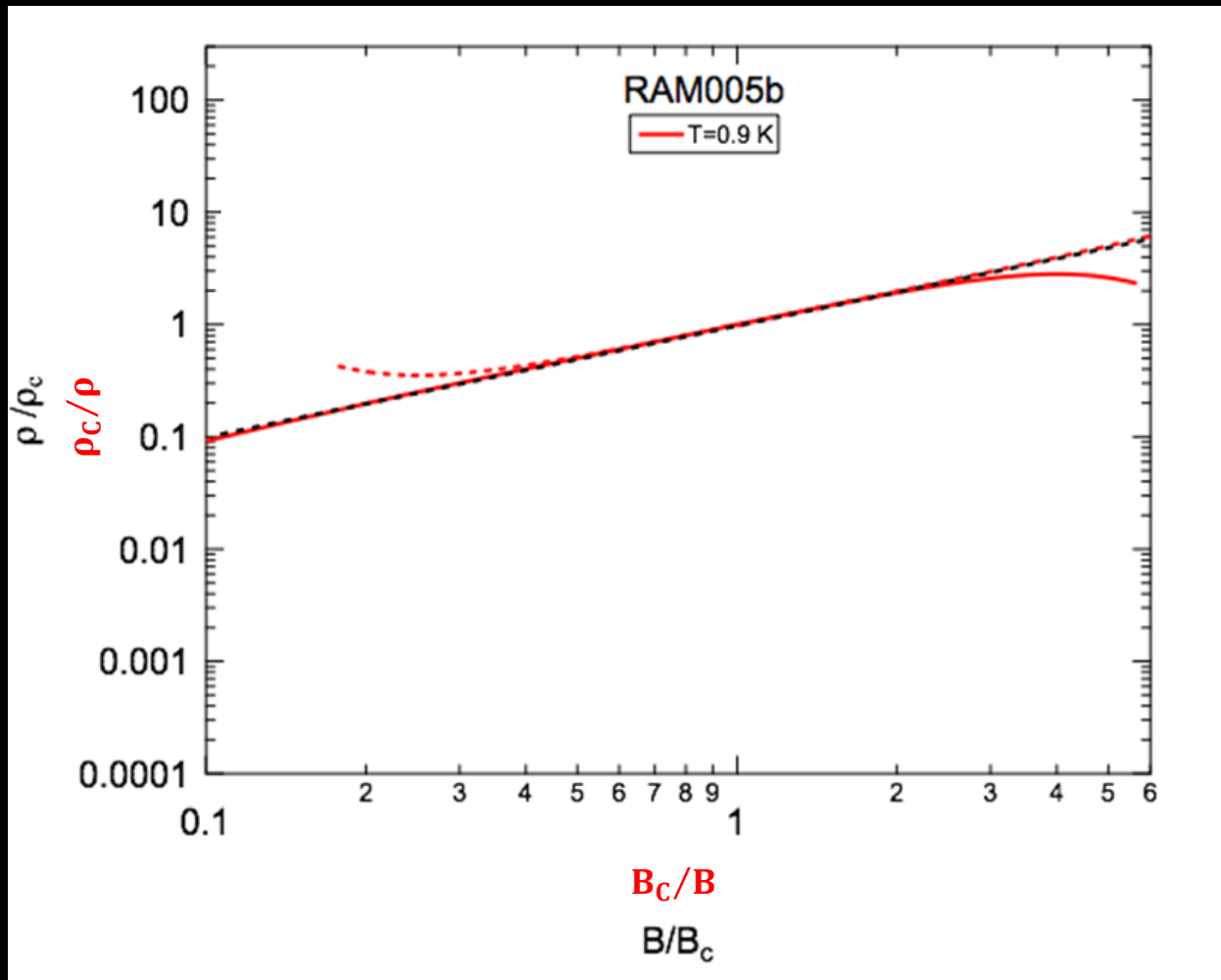




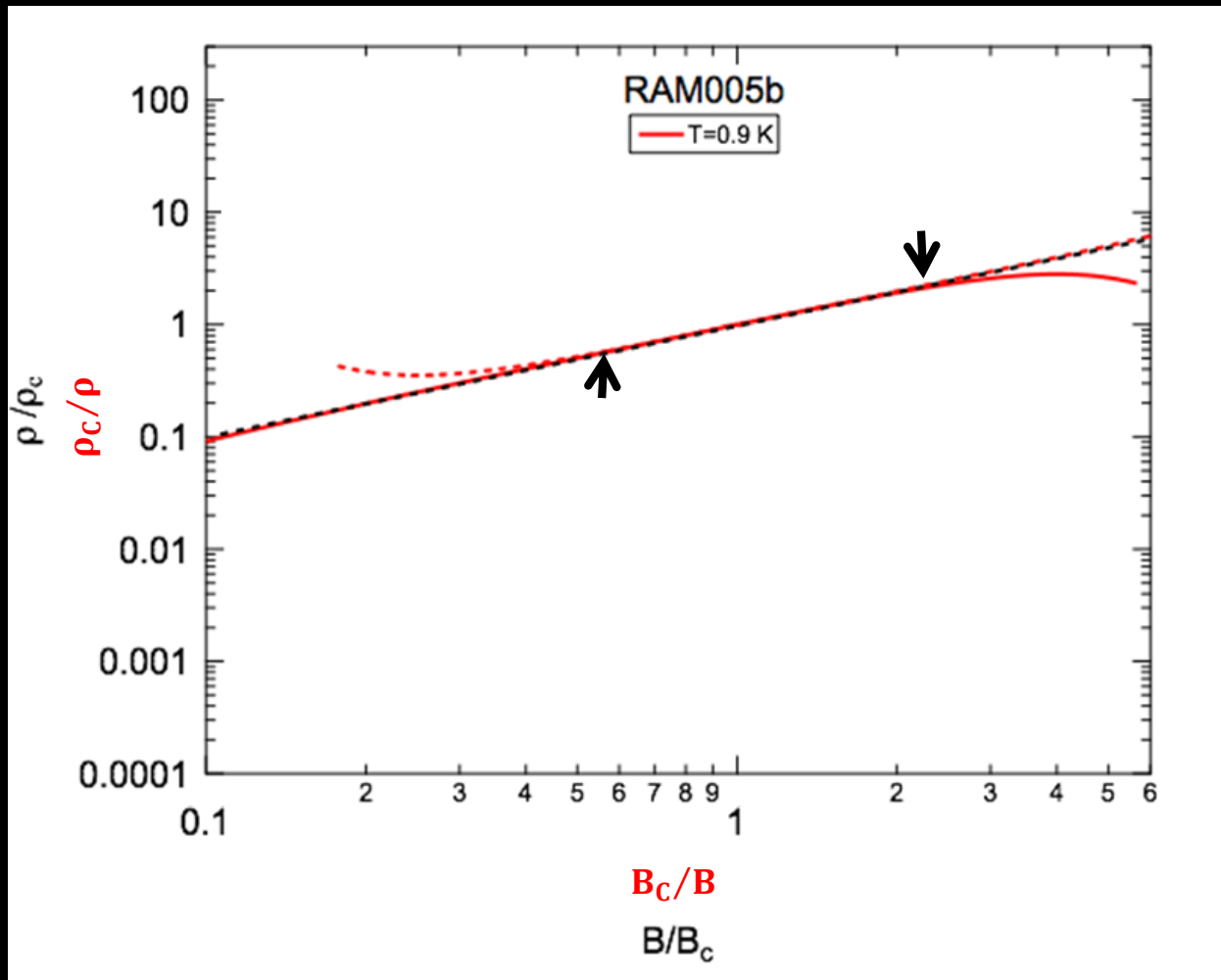
$$\frac{\rho(B, T)}{\rho_C} = \left(\frac{B}{B_C} \right)^{T_0/2T}$$



$$\frac{\rho(B, T)}{\rho_c} = \left(\frac{B}{B_c} \right)^{T_0/2T} \quad \Rightarrow \quad \frac{\rho_c}{\rho(B, T)}$$

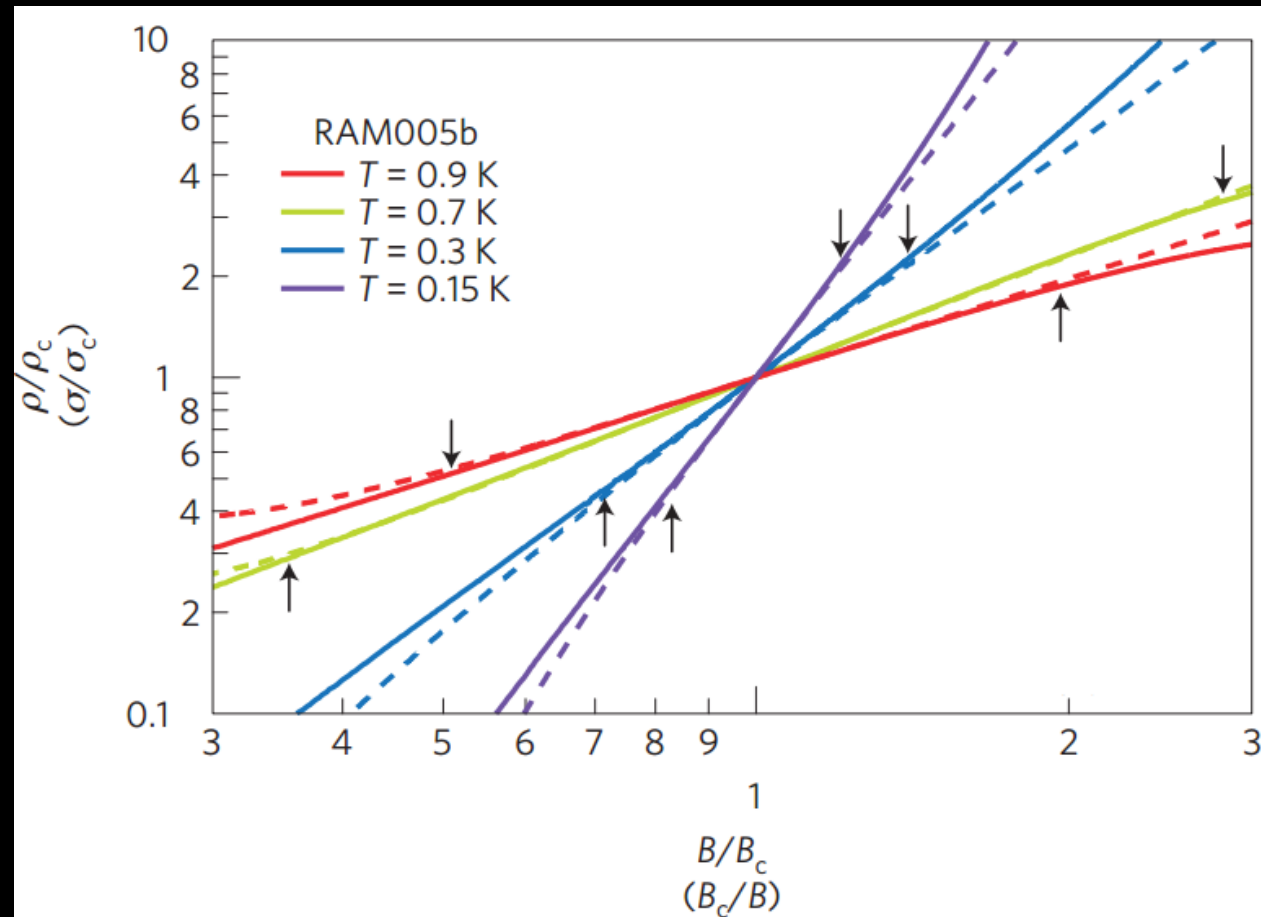


$$\frac{\rho(B, T)}{\rho_c} = \left(\frac{B}{B_c} \right)^{T_0/2T} \quad \Rightarrow \quad \frac{\rho_c}{\rho(B, T)} = \left(\frac{B_c}{B} \right)^{T_0/2T}$$



$$\rho(B_{SC}) = \sigma(B_{Ins})$$

Duality symmetry

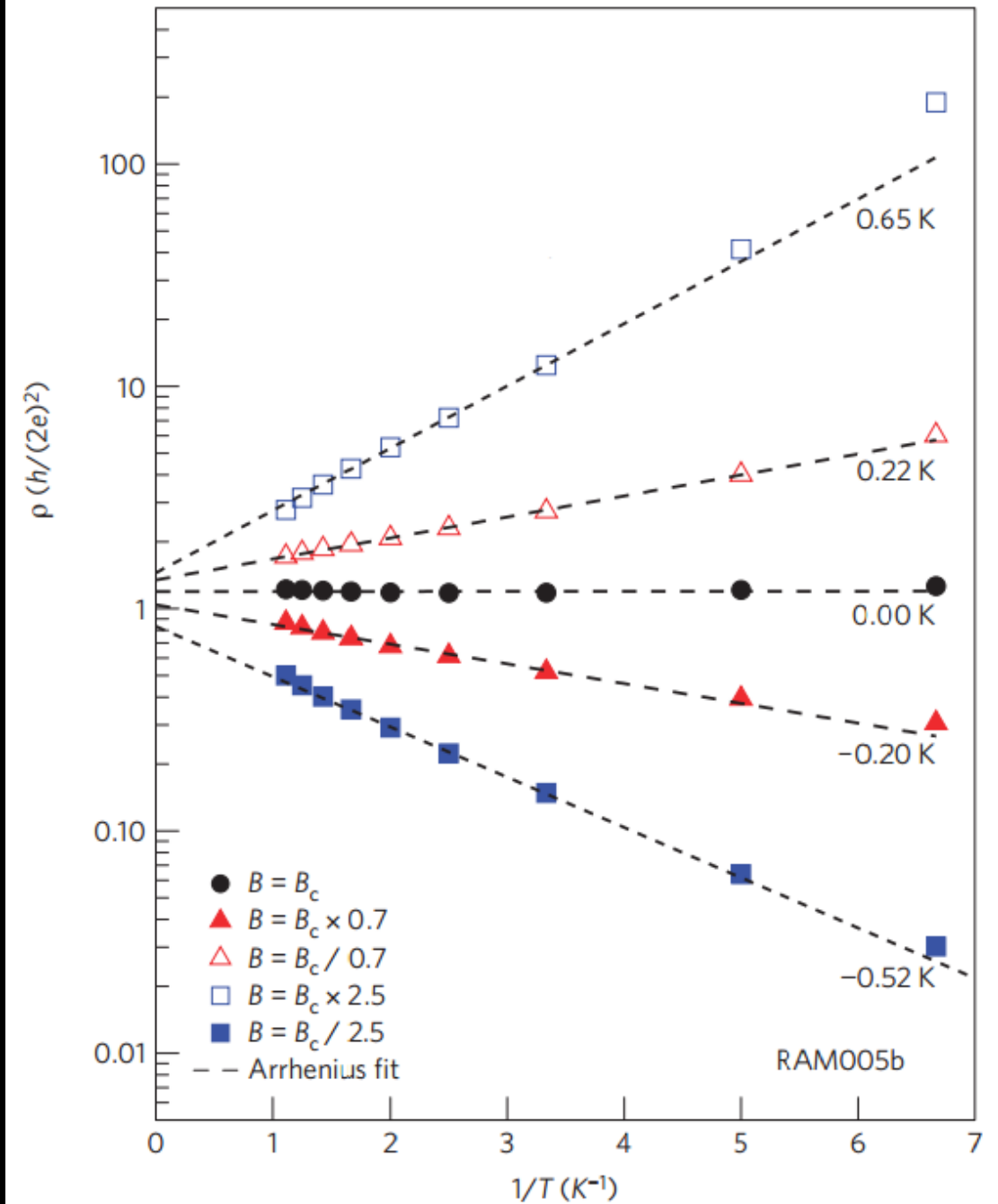


Ovadia, M; Kalok, D; Sacepe, B; Shahar, D (2013). Duality Symmetry and Its Breakdown in the Vicinity of the Superconductor-Insulator Transition. Nature Physics. 9:415-418.

Resistance Temperature Dependence

$$\rho(B, T) = \rho_c \times \exp\left(\frac{E_0(B)}{k_B T}\right)$$

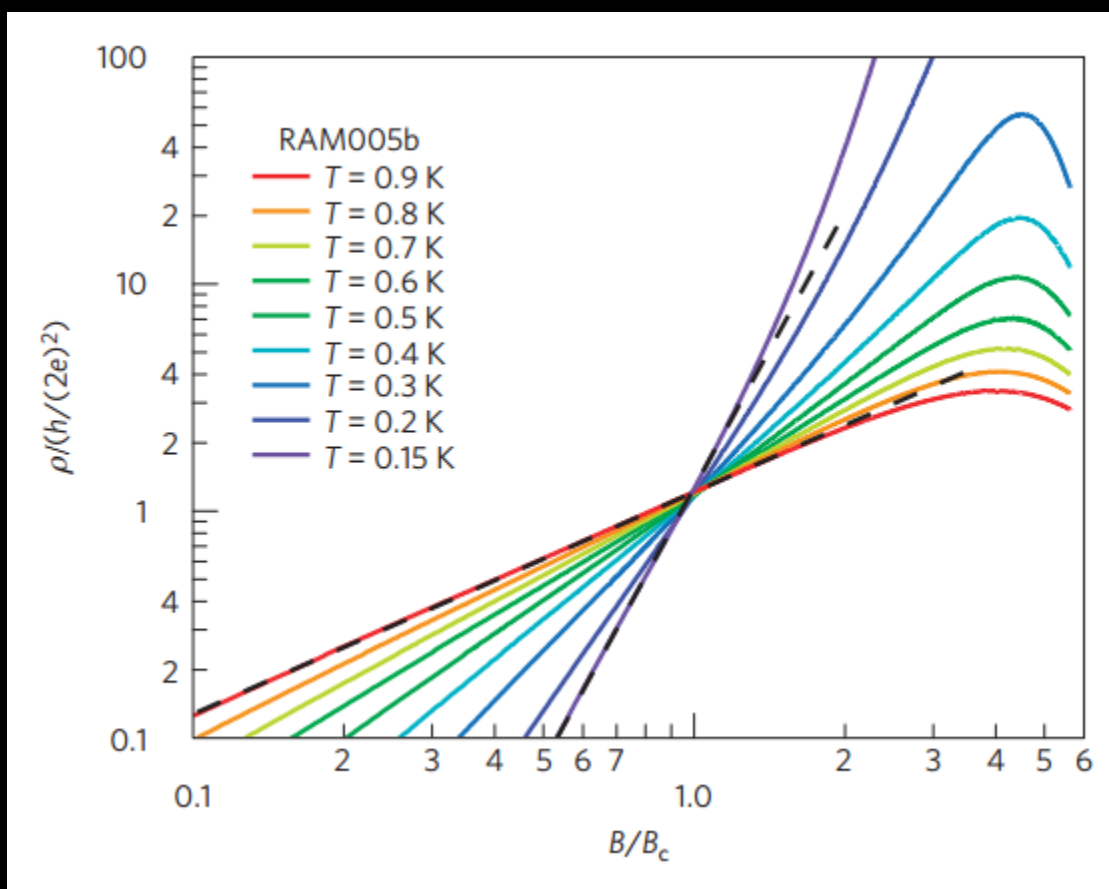
$$E_0(B_{SC}) = -E_0(B_{Ins})$$



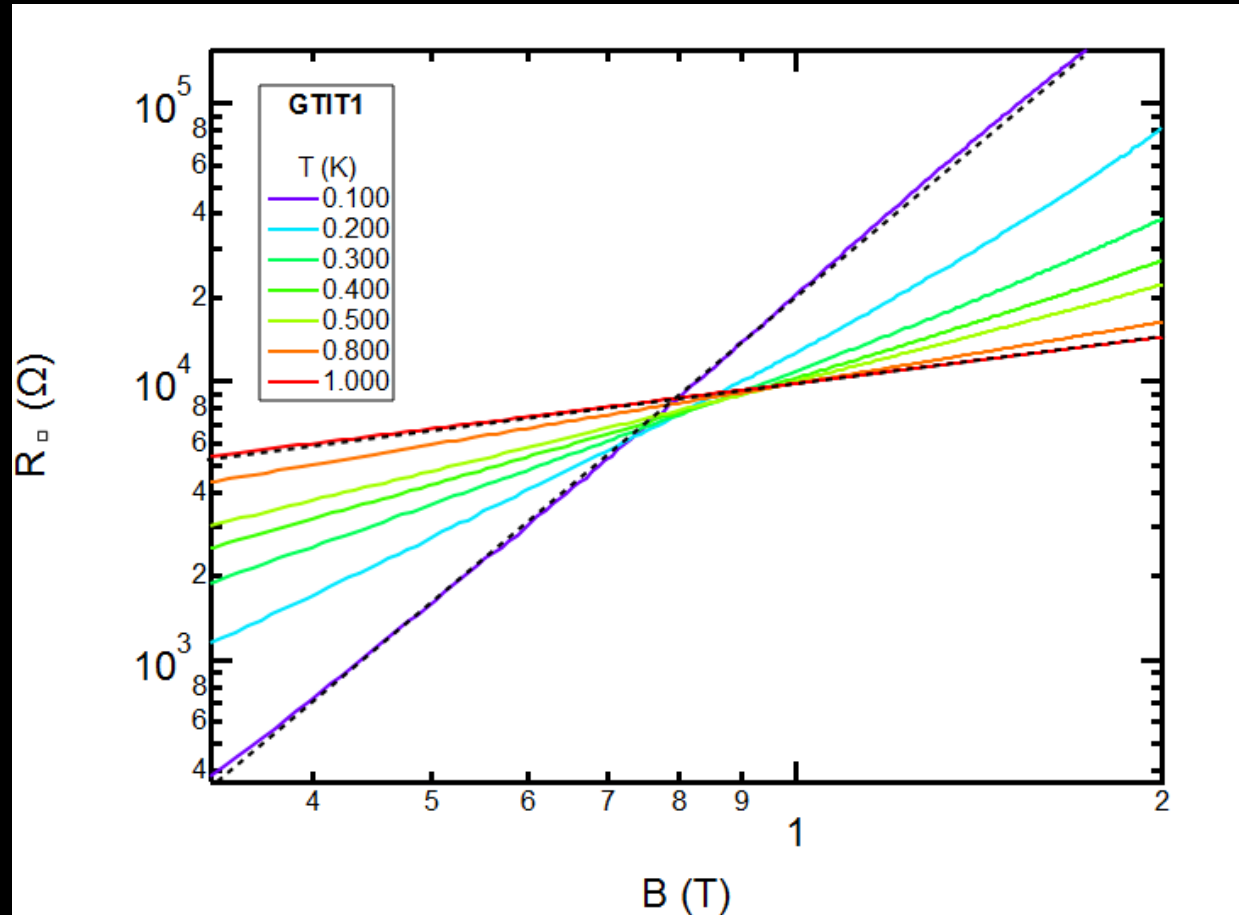
(very) Low Temperature

Duality symmetry and its breakdown in the vicinity of the superconductor-insulator transition

Maoz Ovadia, David Kalok^{*}, Benjamin Sacépé[†] and Dan Shahar



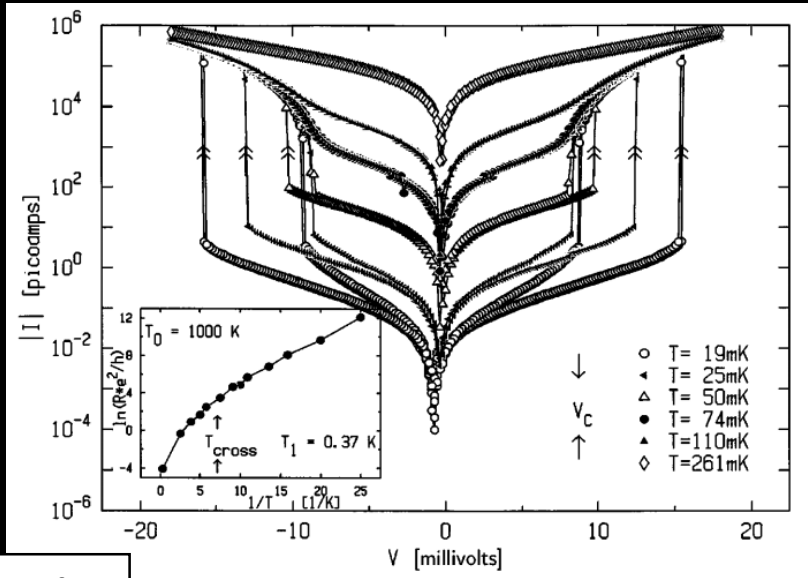
Low Temperature Duality Breakdown



Properties of a CPI

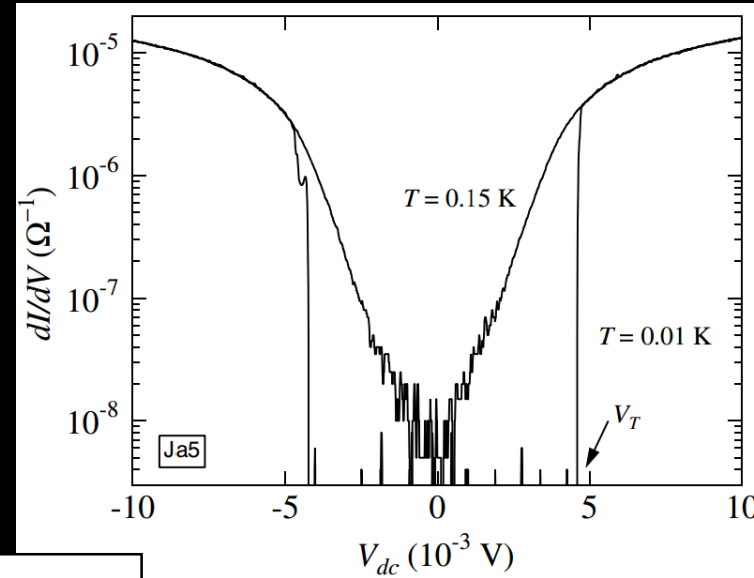
- ❖ Exponential temperature dependence of the resistance
- ❖ Electrons are interacting and decoupled from phonons

Discontinuous Current-Voltage Characteristics in CPI's



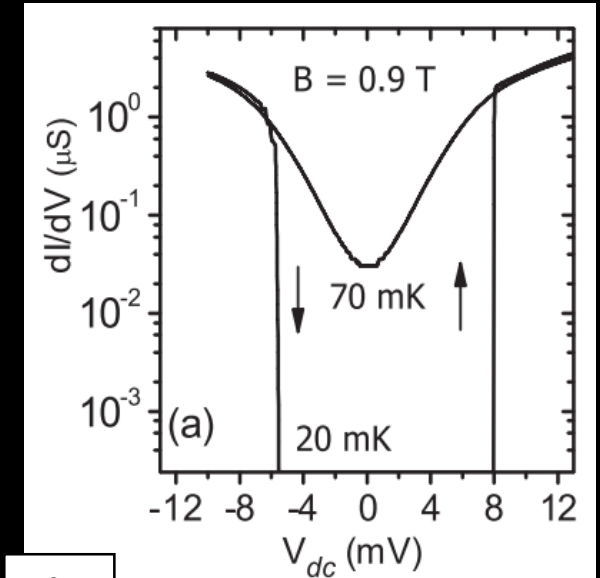
Y_xSi_{1-x}

F. Ladieu, M. Sanquer, and J. P. Bouchaud, Phys. Rev. B 53, 973 (1996).



a:InO

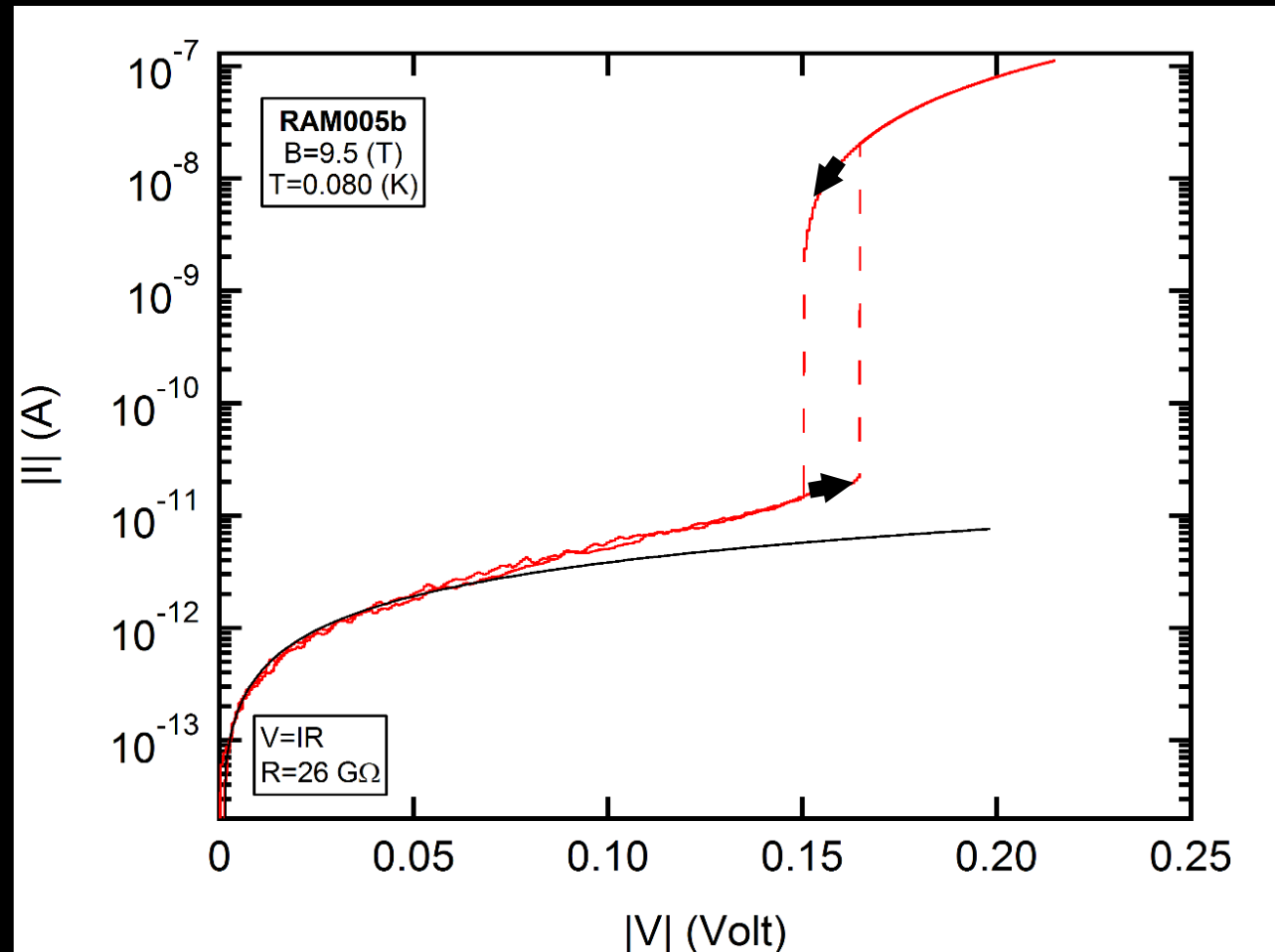
Sambandamurthy, G; Engel, L.w; Johansson, A; Peled, E; Shahar, D (2005). Experimental Evidence For a Collective Insulating State in Two-Dimensional Superconductors. Physical Review Letters. 94.



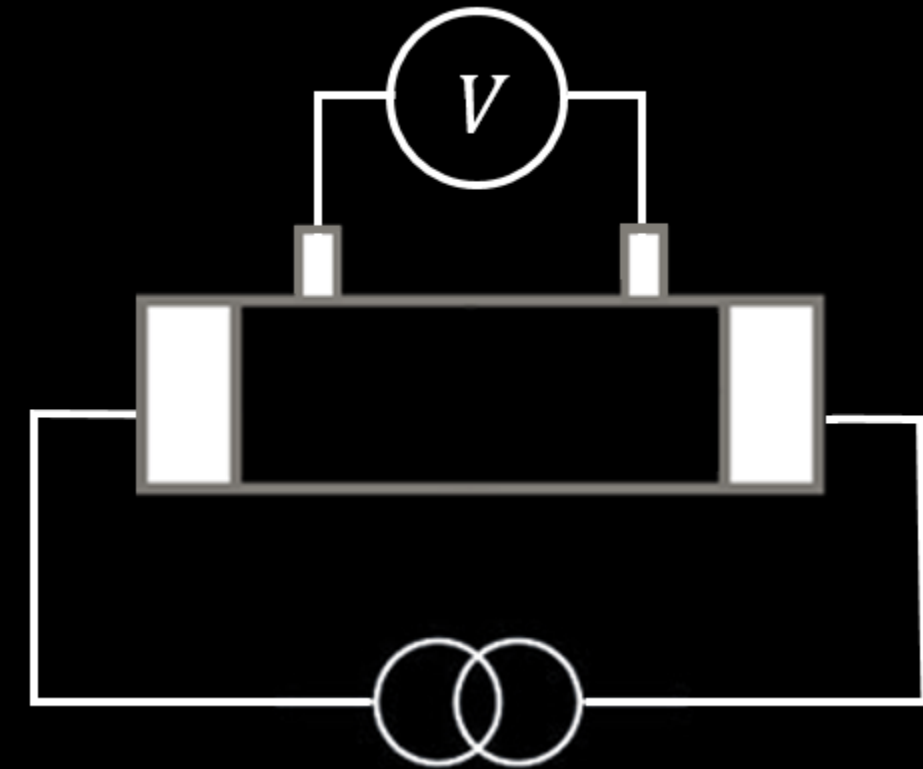
TiN

T. Baturina, A. Y. Mironov, V. Vinokur, M. Baklanov, and C. Strunk, Phys. Rev. Lett. 99, 257003 (2007)

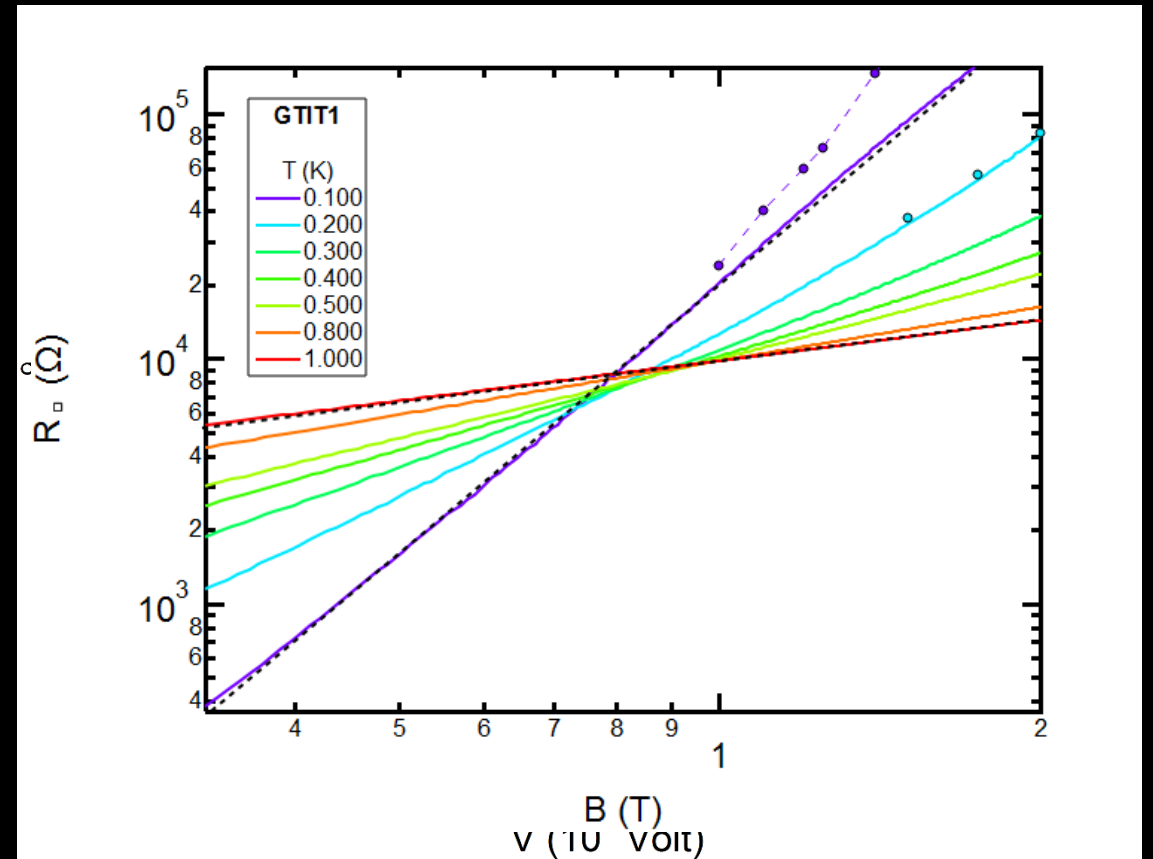
Current-Voltage Characteristics



4 Probe Measurement



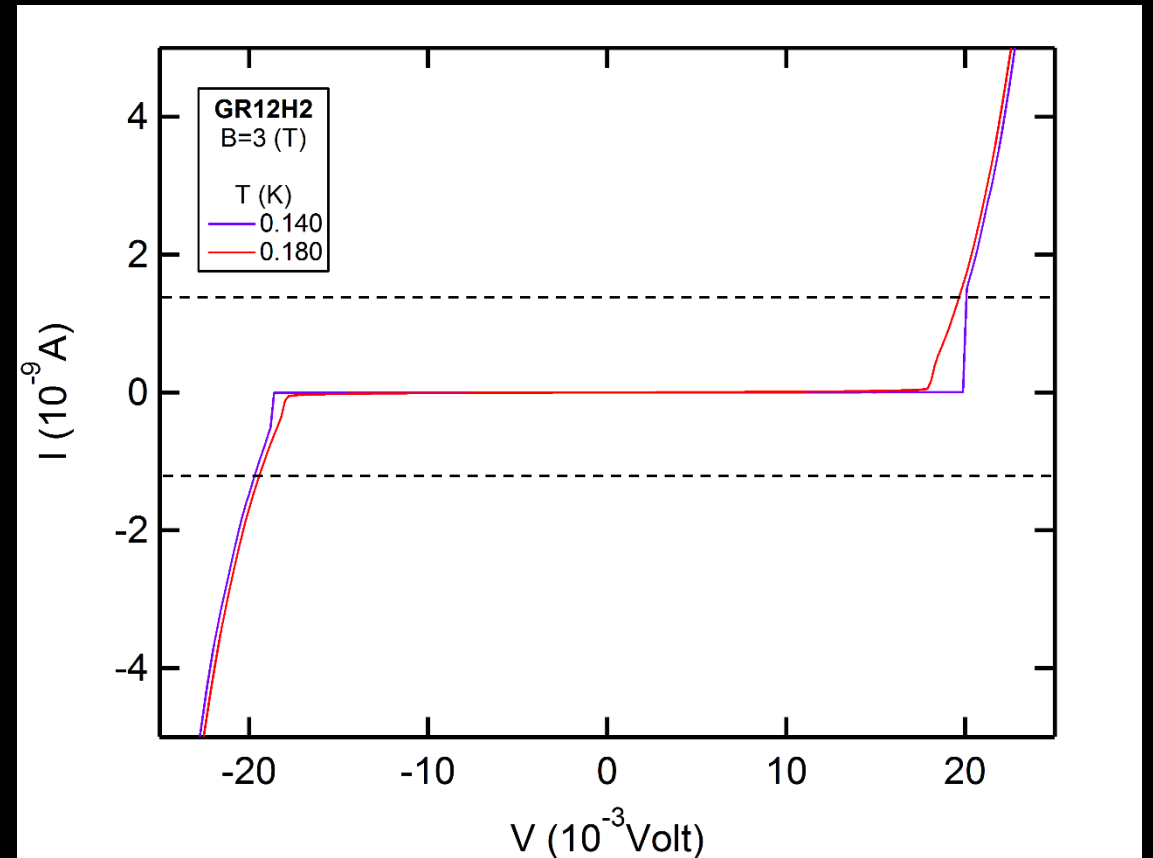
$I_{ac} \sim 1nA$



Doron, A., Tamir, I., Levinson, T., Ovidia, M., Sacépé, B., & Shahar, D. (2016). Transport Catastrophe Near the Superconductor-Insulator Transition. *arXiv preprint arXiv:1606.06606*.

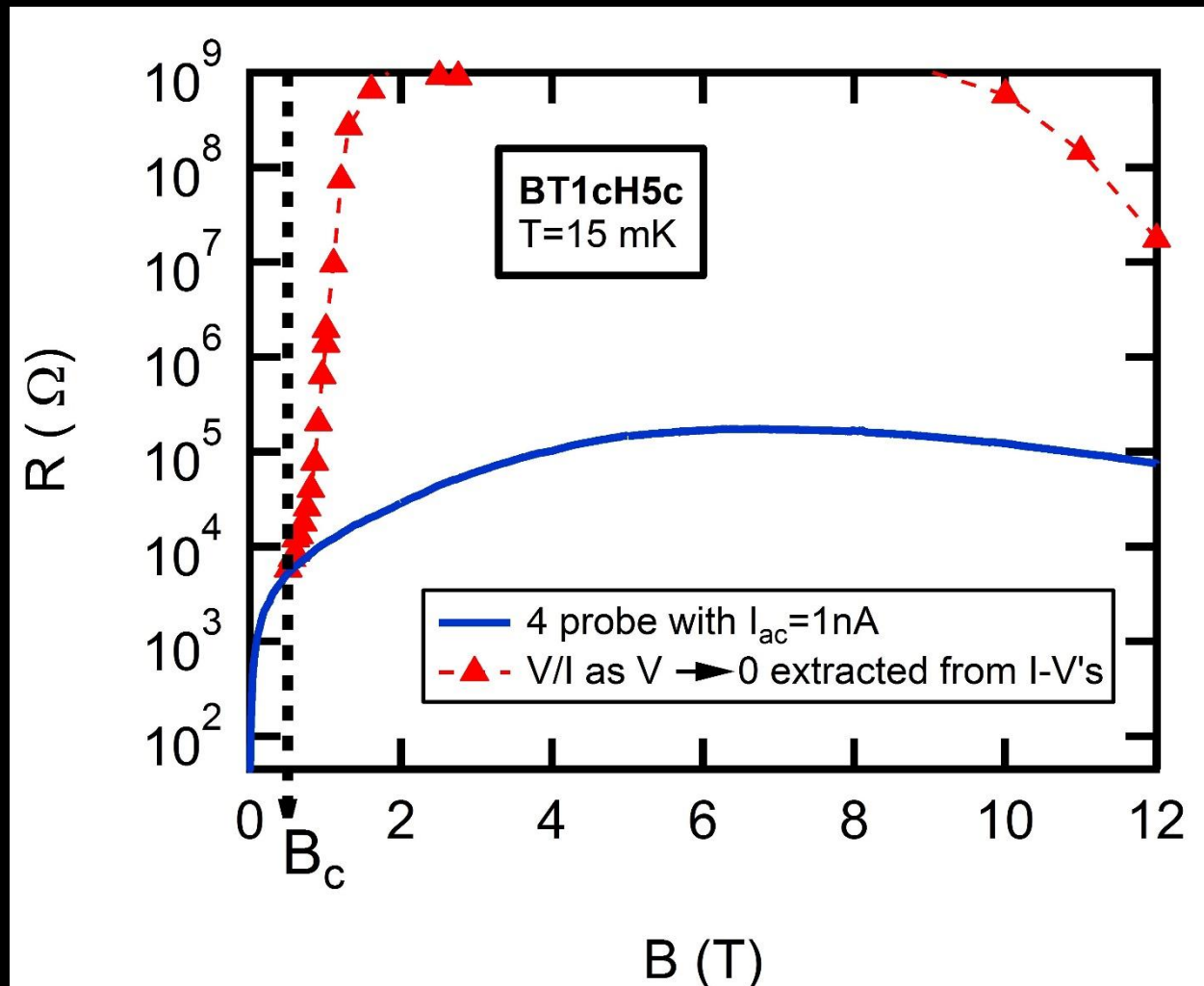
4 Probe Measurement

- 1 nA is allowed \rightarrow Sampling mostly the high current branch without knowing (high current branch is linear).
- 1 nA is in the unstable region. Not clear what is measured.

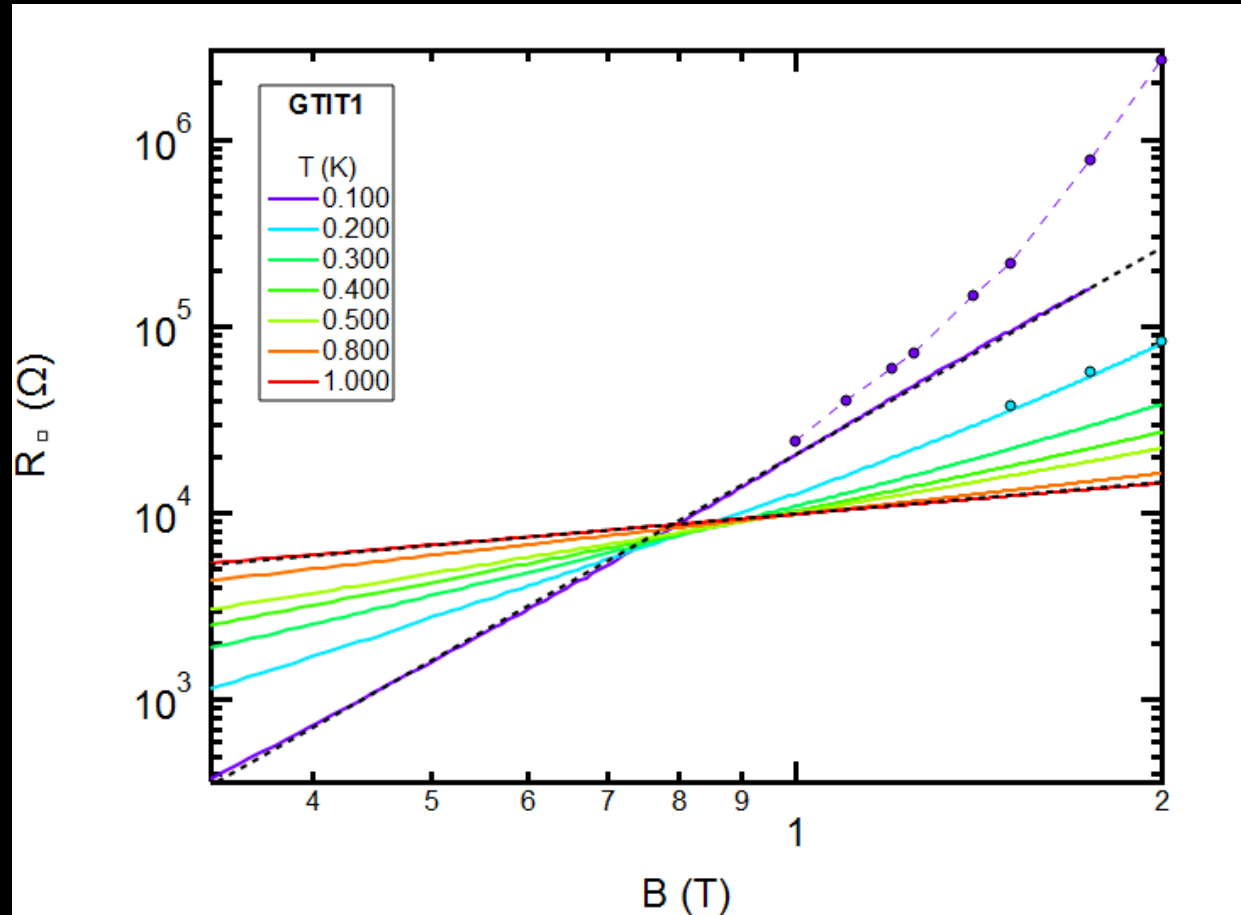


Doron, A., Tamir, I., Levinson, T., Ovidia, M., Sacépé, B., & Shahar, D. (2016). Transport Catastrophe Near the Superconductor-Insulator Transition. *arXiv preprint arXiv:1606.06606*.

4 Probe Catastrophe

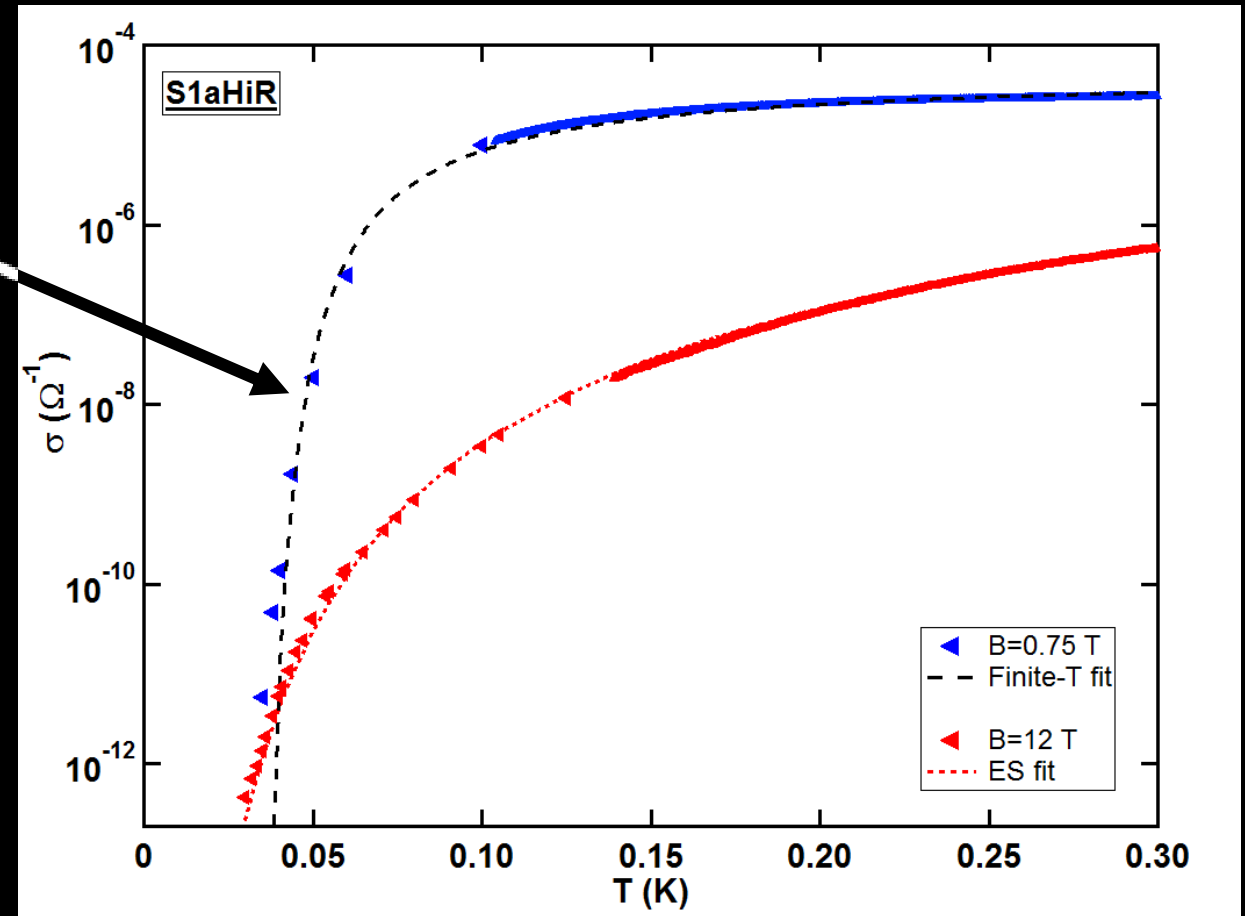


Low Temperature Duality Breakdown



Low Temperature Conductivity

$$\sigma(T) = \sigma_0 \times \exp\left\{-\frac{T_0}{T - T^*}\right\}$$



Ovadia, M.; Kalok, D.; Tamir, I.; Mitra, S.; Sacepe, B.; Shahar, D. (2015). Evidence For a Finite-Temperature Insulator. Scientific Reports. 5:13503.

Possible experimental manifestations of the many-body localization

D. M. Basko,^{1,*} I. L. Aleiner,¹ and B. L. Altshuler^{1,2}

¹*Physics Department, Columbia University, New York, New York 10027, USA*

²*NEC-Laboratories America, Inc., 4 Independence Way, Princeton, New Jersey 08540, USA*

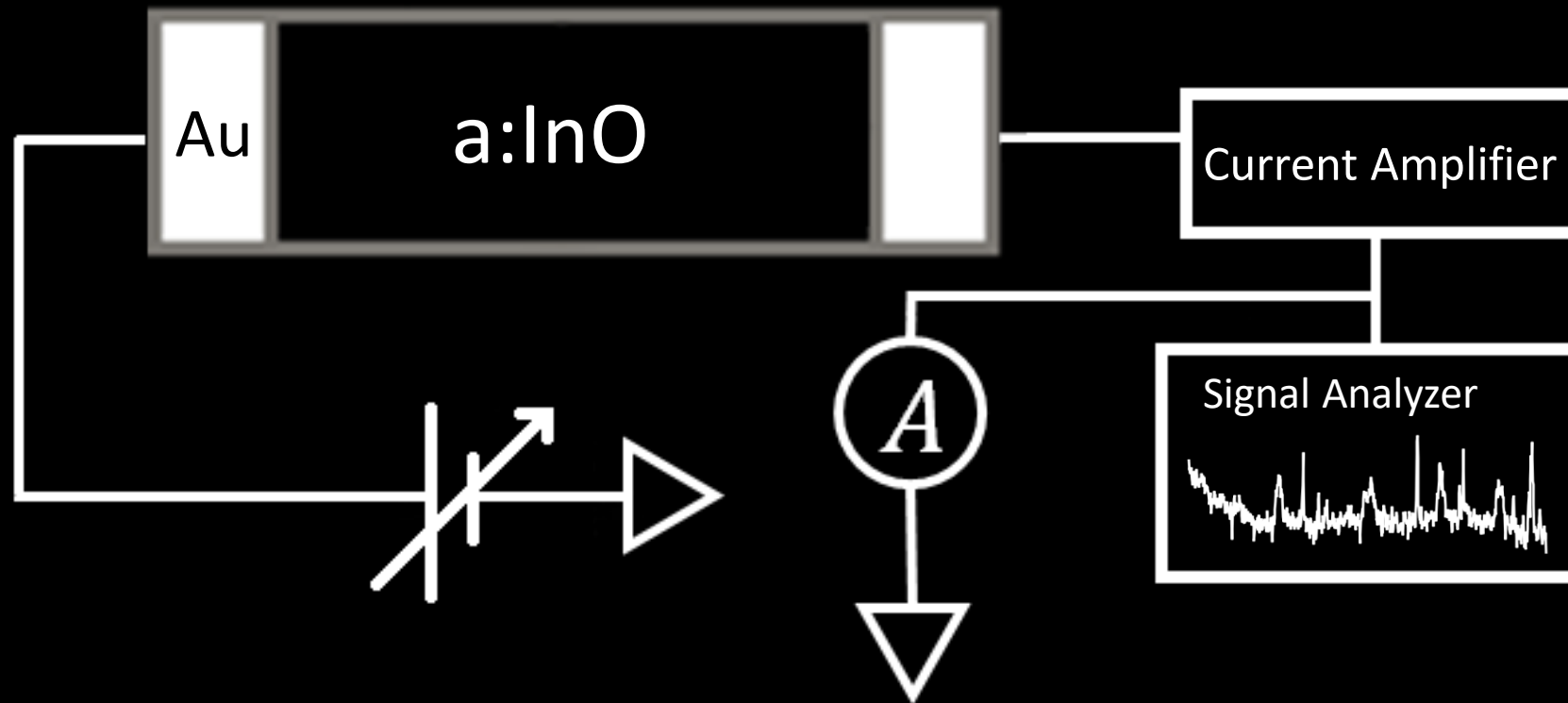
(Received 24 July 2007; published 23 August 2007; publisher error corrected 14 September 2007)

Recently, it was predicted that if all one-electron states in a noninteracting disordered system are localized, the interaction between electrons in the absence of coupling to phonons leads to a finite-temperature metal-insulator transition. Here, we show that even in the presence of a weak coupling to phonons the transition manifests itself (i) in the nonlinear conduction, leading to a bistable I - V curve, and (ii) by a dramatic enhancement of the nonequilibrium current noise near the transition.

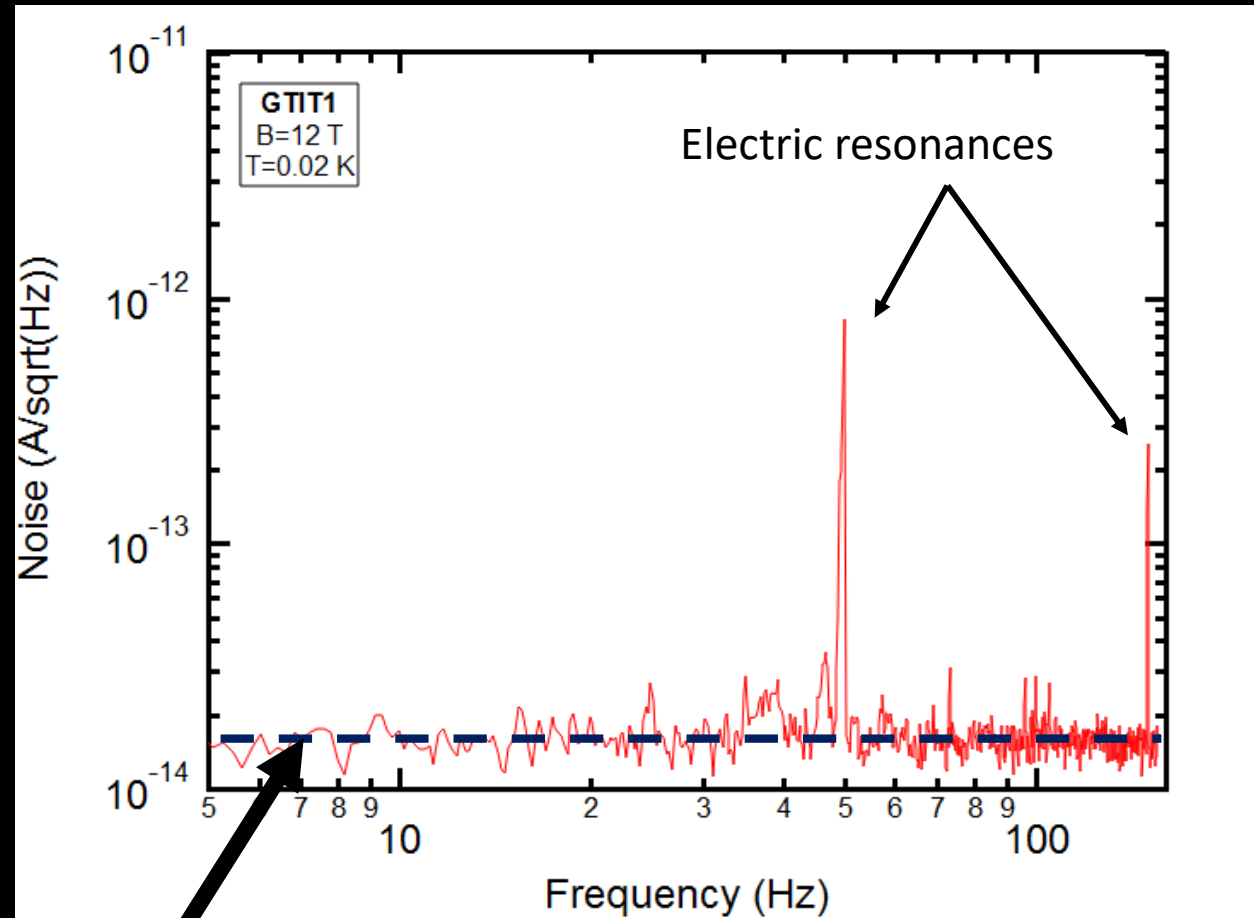
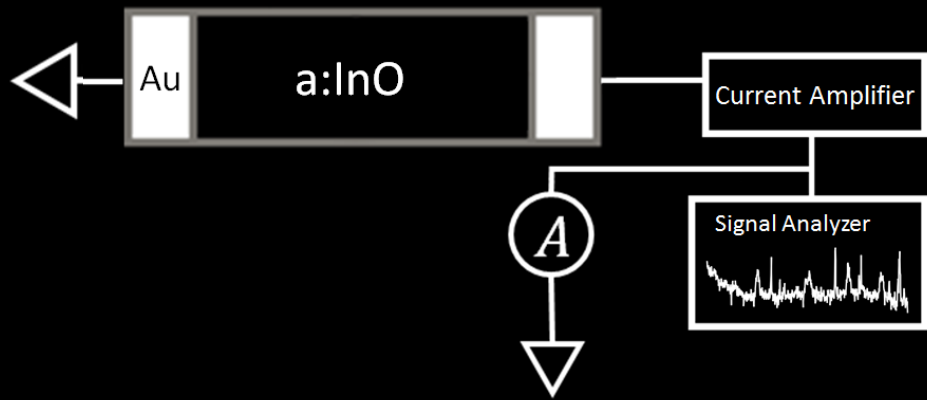
DOI: [10.1103/PhysRevB.76.052203](https://doi.org/10.1103/PhysRevB.76.052203)

PACS number(s): 72.10.-d, 72.15.Rn, 72.20.Ee, 72.60.+g

Noise Measurement - Setup

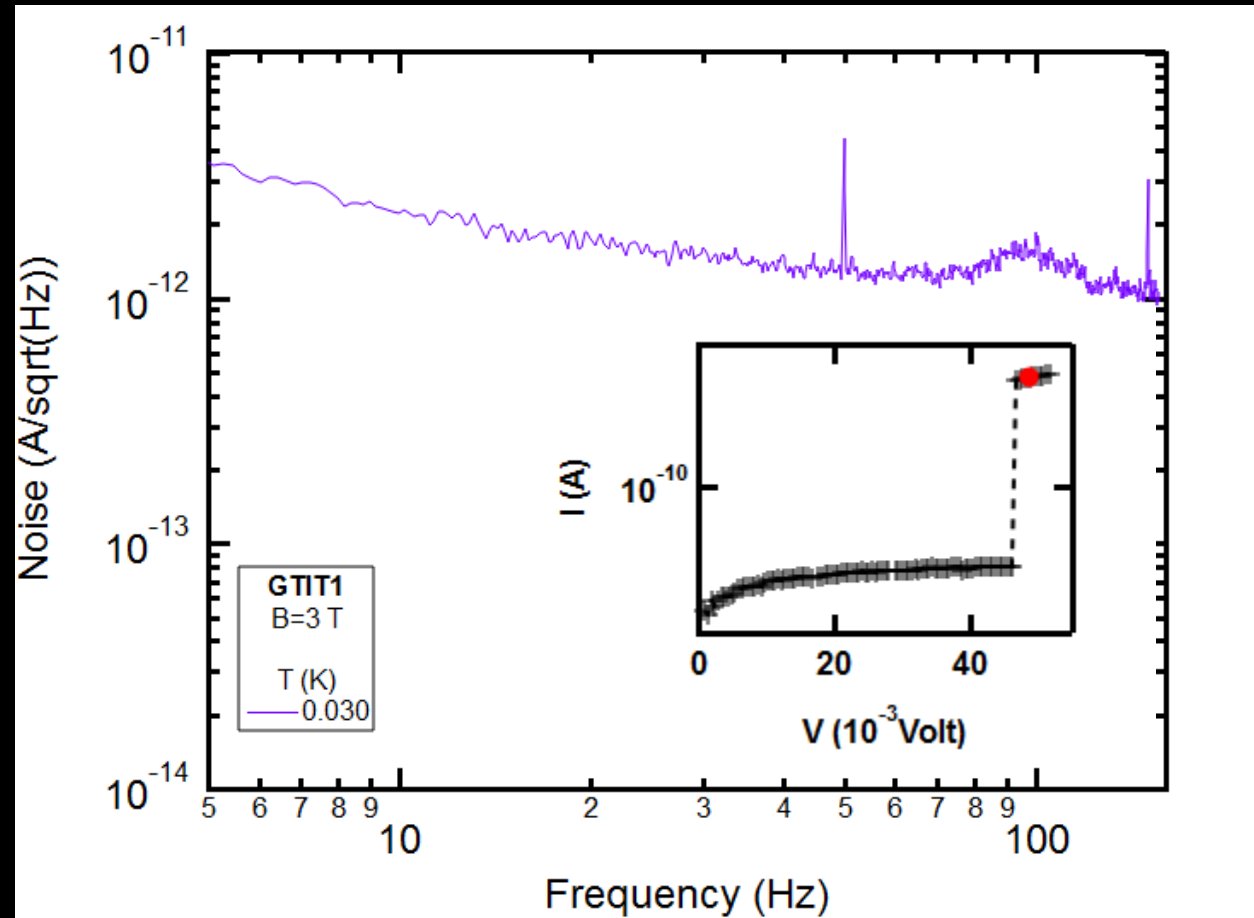
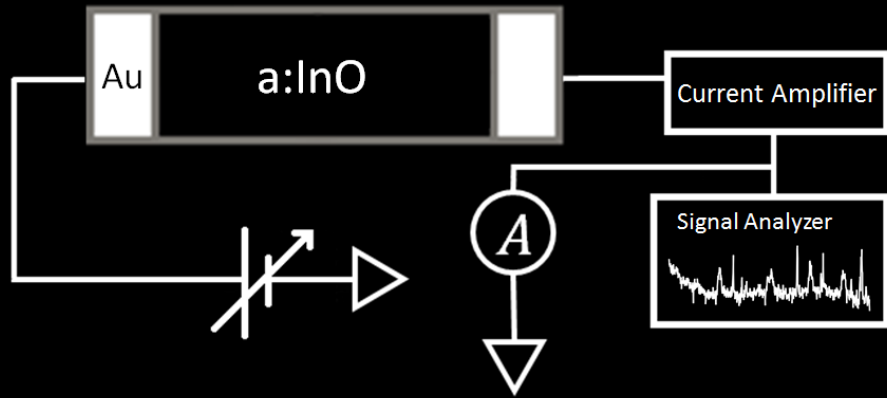


Noise Spectral Density – $V = 0$



Amplifier baseline noise

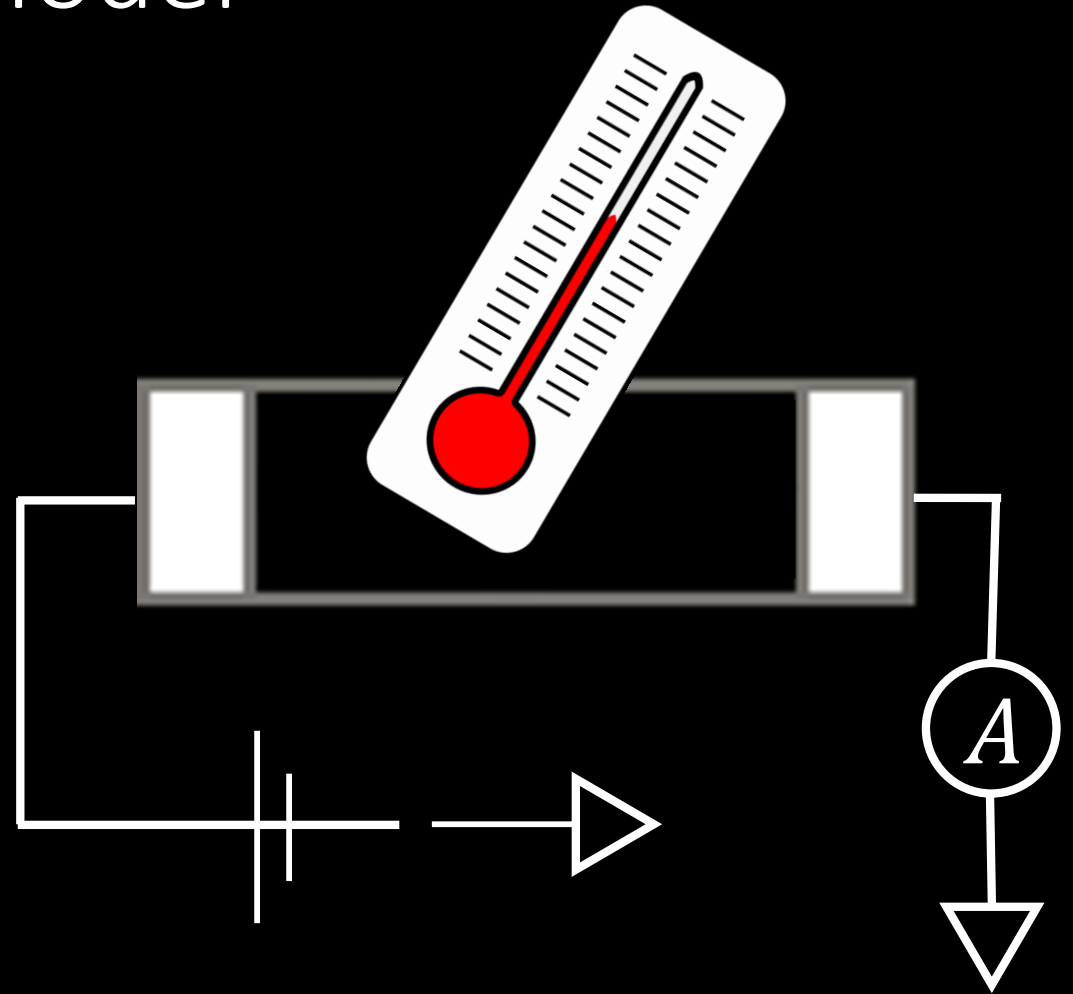
Noise Spectral Density – $V \neq 0$



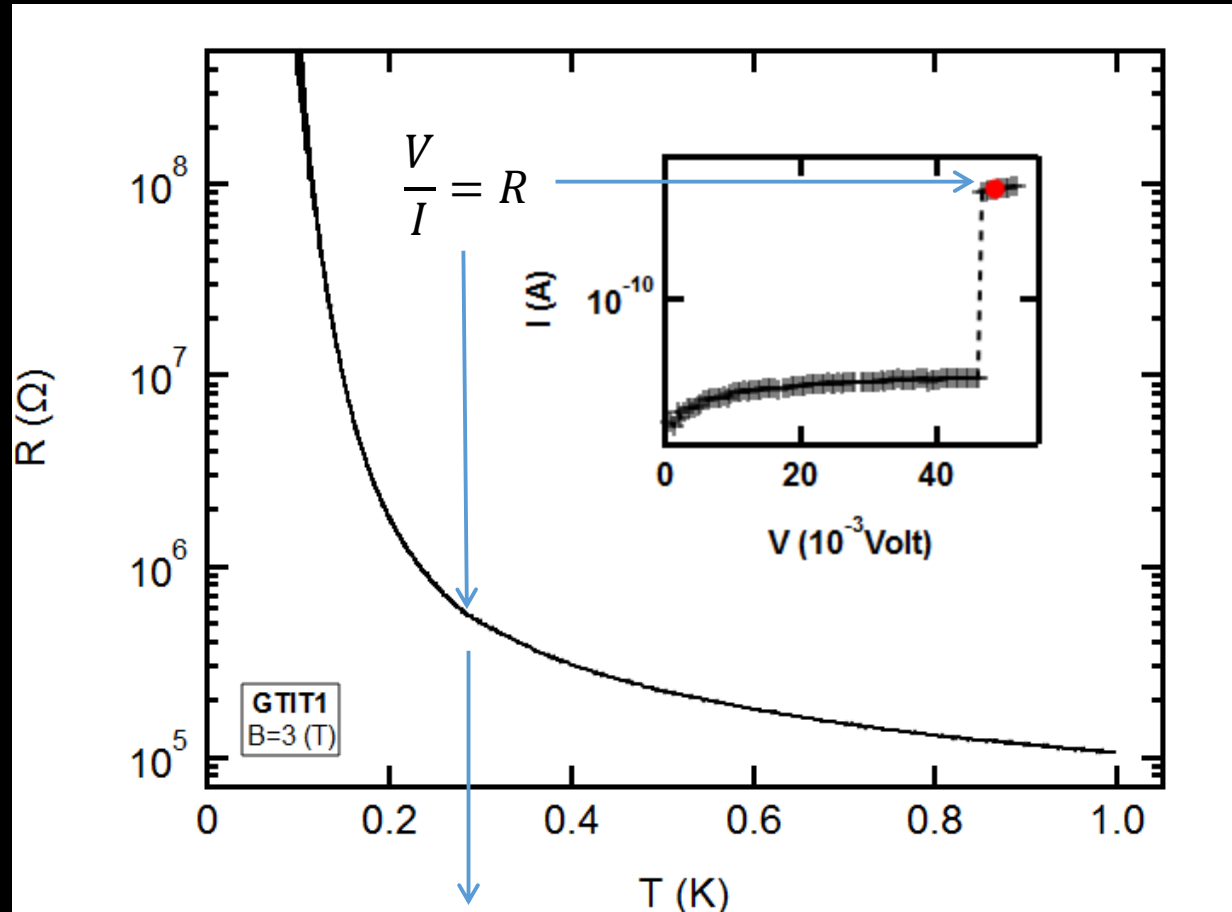
Noise Thermometry – Over-Heated electron Model

- Primary Thermometer
- Coupled directly to the electrons

- $Noise \propto \sqrt{\frac{4kT_{el}}{R}}$

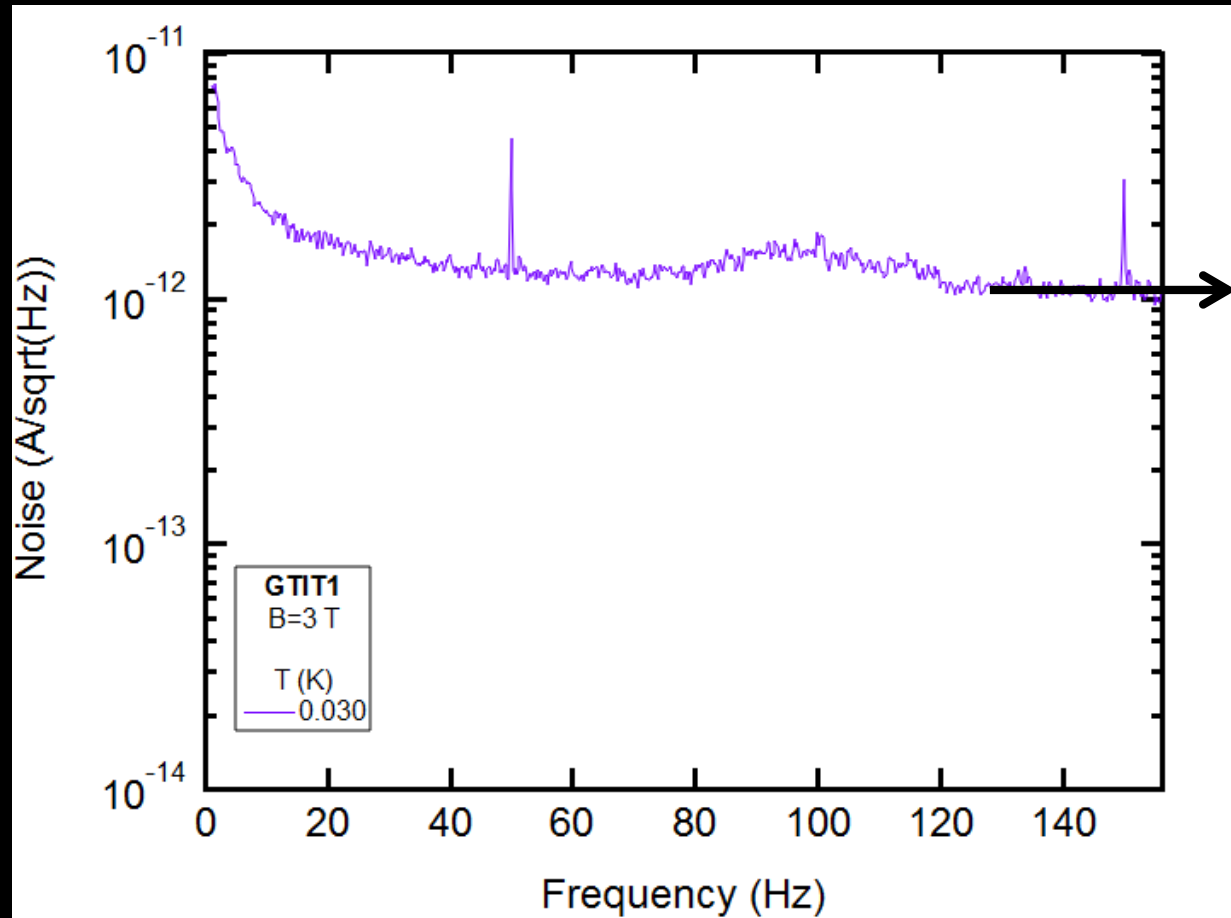


Over-Heated electron Model



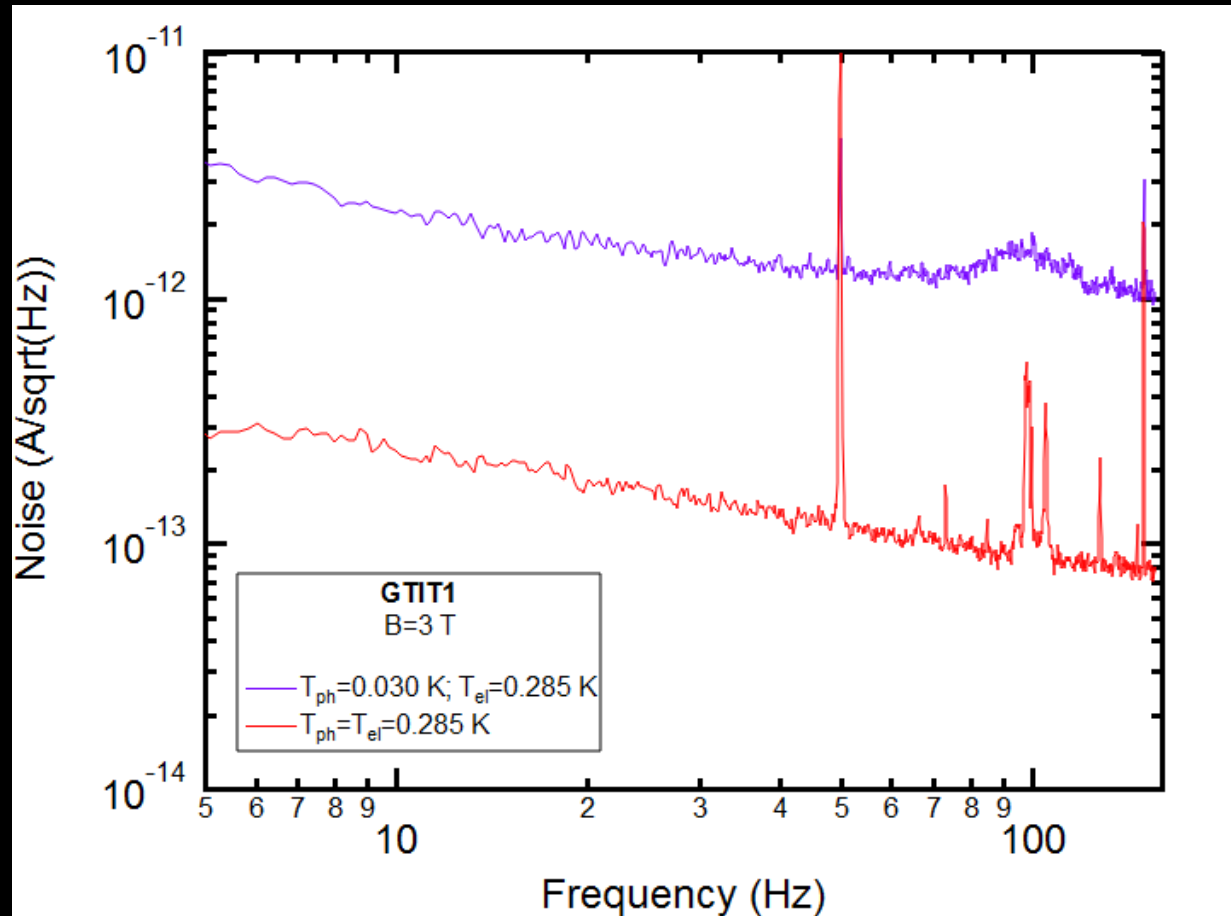
$$T_{el} \sim 0.285 \text{ K}$$

Noise Spectral Density – $V \neq 0$

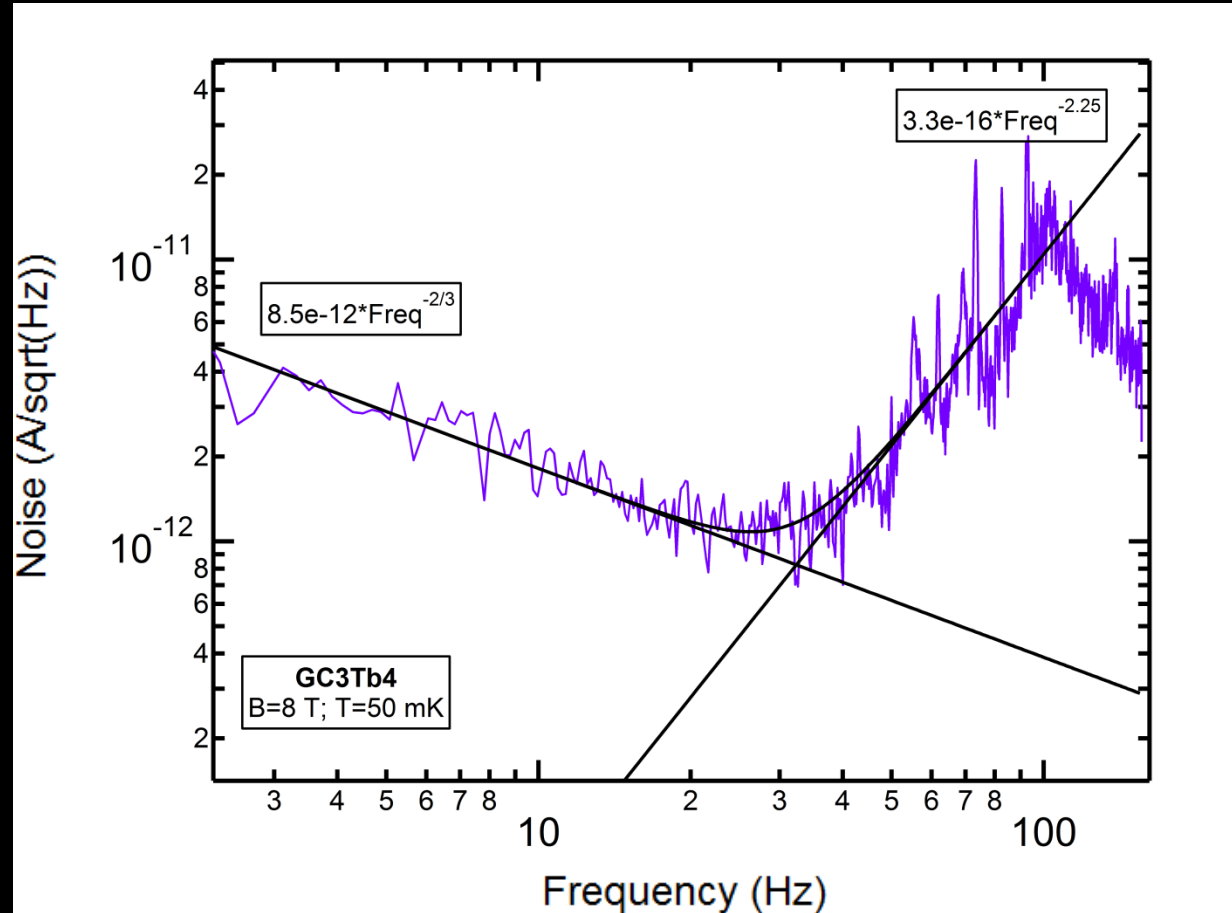


$T \sim 3000 K$

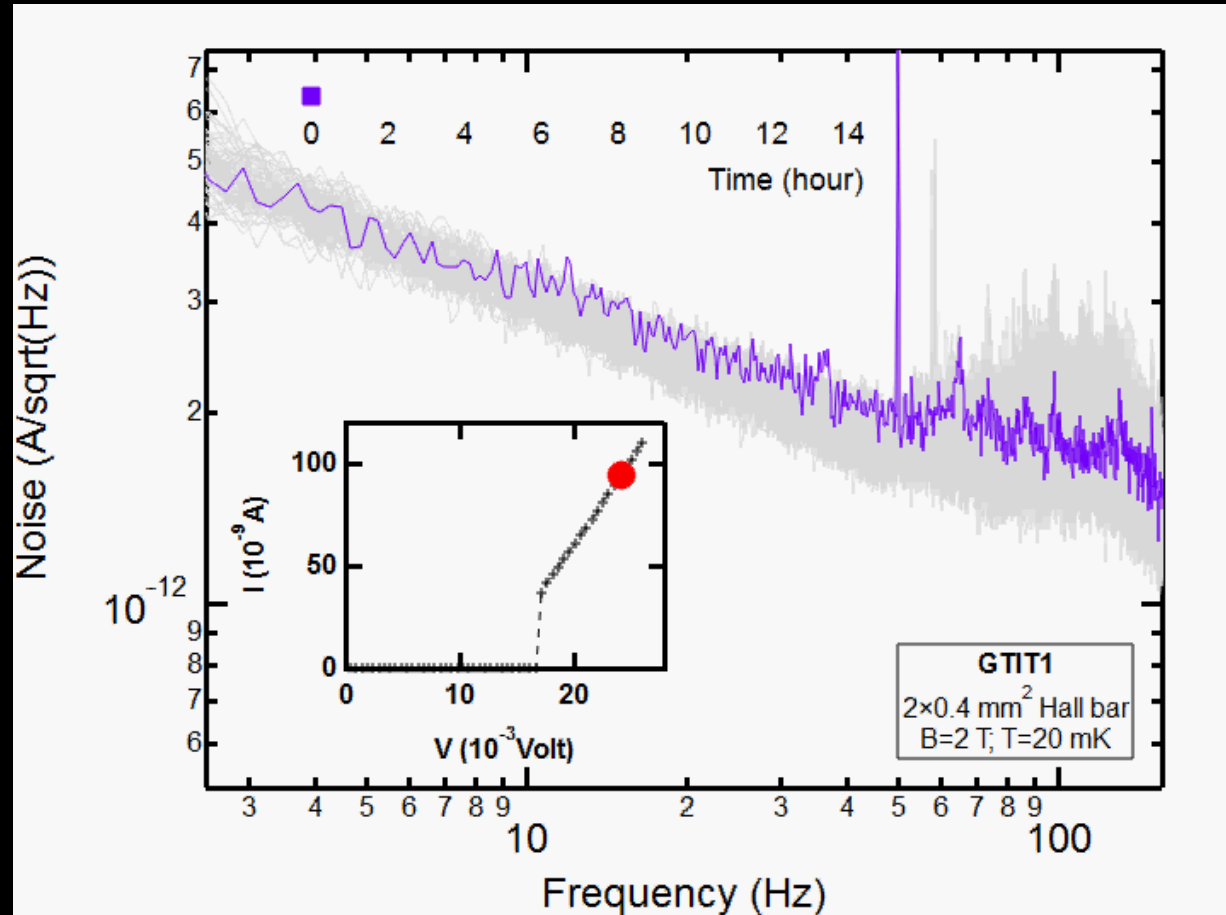
Noise Spectral Density – $T_{el} = T_{ph}$



Noise Peak



Noise Peak – Time dependence



Low Temperature Summary

- Duality symmetry is broken
- Instability of the $I - V$ characteristics is observed
- Resistance (calculated from $I - V$'s) show strong temperature dependence, despite $e-ph$ decoupling
- Large (time dependent) noise is observed as an applied V bias is introduced

Thank You!